

## FEATURES

- Single input voltage range from 5V to 21V
- Wide input voltage range from 1.0V to 21V with external  $V_{CC}$  bias voltage
- Output voltage range from 0.6V to 0.86%  $P_{VIN}$
- Enhanced line/load regulation with feedforward
- Programmable switching frequency up to 1.2MHz
- Three user selectable soft-start time
- User selectable LDO output voltage
- Enable input with voltage monitoring capability
- Thermally compensated current limit with robust hiccup mode over current protection
- Synchronization to an external clock
- Enhanced Pre-bias start-up
- Precise reference voltage (0.6V $\pm$ 0.6%)
- Open-drain PGood indication
- Optional power up sequencing
- Integrated MOSFET drivers and bootstrap diode
- Thermal Shut Down
- Monotonic Start-Up
- Operating temp: -40°C <  $T_j$  < 125°C
- Package size: 4mm x 5mm PQFN
- Lead-free, Halogen-free and RoHS6 Compliant

## DESCRIPTION

The IR3827 SupIRBuck™ is an easy-to-use, fully integrated and highly efficient DC/DC regulator. The onboard PWM controller and MOSFETs make IR3827 a space-efficient solution, providing accurate power delivery for low output voltage applications.

IR3827 is a versatile regulator which offers programmable switching frequency and internally set current limit while operating in wide range of input and output voltage conditions.

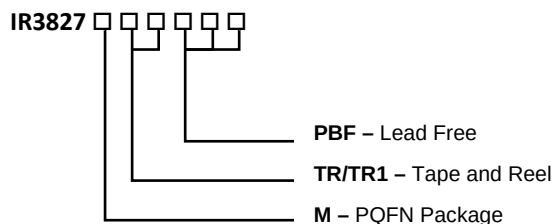
The switching frequency is programmable from 300kHz to 1.2MHz for an optimum solution. It also features important protection functions, such as Pre-Bias startup, thermally compensated current limit, over voltage protection and thermal shutdown to give required system level security in the event of fault conditions.

## APPLICATIONS

- Computing Applications
- Set Top Box Applications
- Storage Applications
- Data Center Applications
- Distributed Point of Load Power Architectures

## ORDERING INFORMATION

| Base Part Number | Package Type     | Standard Pack |          | Orderable Part Number |
|------------------|------------------|---------------|----------|-----------------------|
|                  |                  | Form          | Quantity |                       |
| IR3827           | PQFN 4 mm x 5 mm | Tape and Reel | 750      | IR3827MTR1PBF         |
| IR3827           | PQFN 4 mm x 5 mm | Tape and Reel | 4000     | IR3827MTRPBF          |



## BASIC APPLICATION

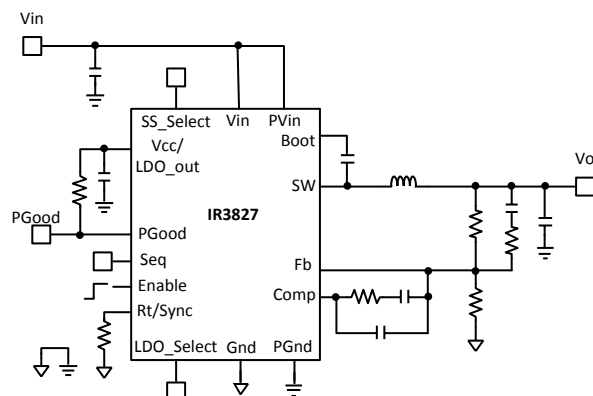


Figure 1 IR3827 Basic Application Circuit

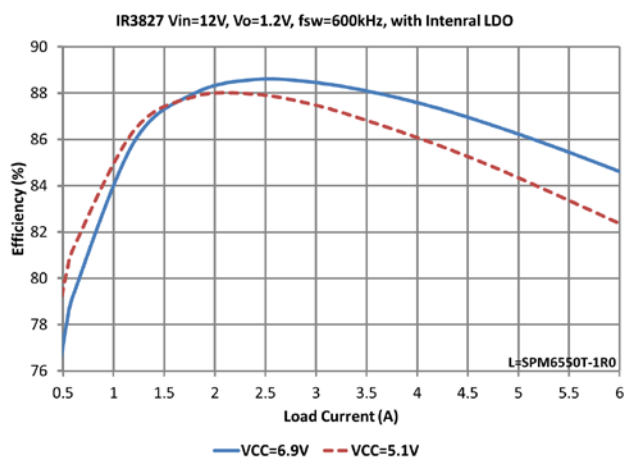


Figure 2 IR3827 Efficiency

## PINOUT DIAGRAM

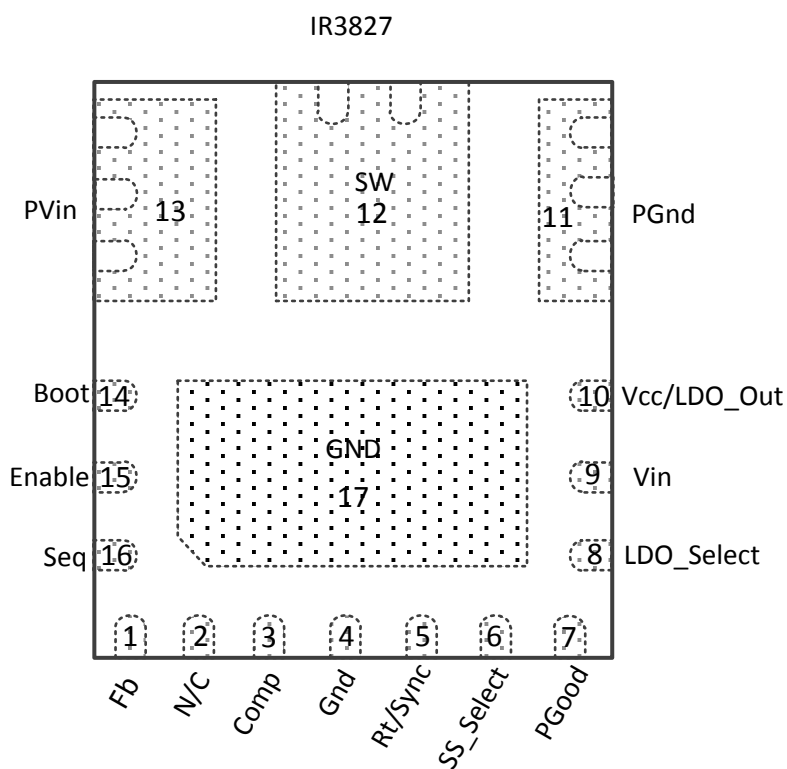


Figure 3 4mm x 5mm PQFN (Top View)

# BLOCK DIAGRAM

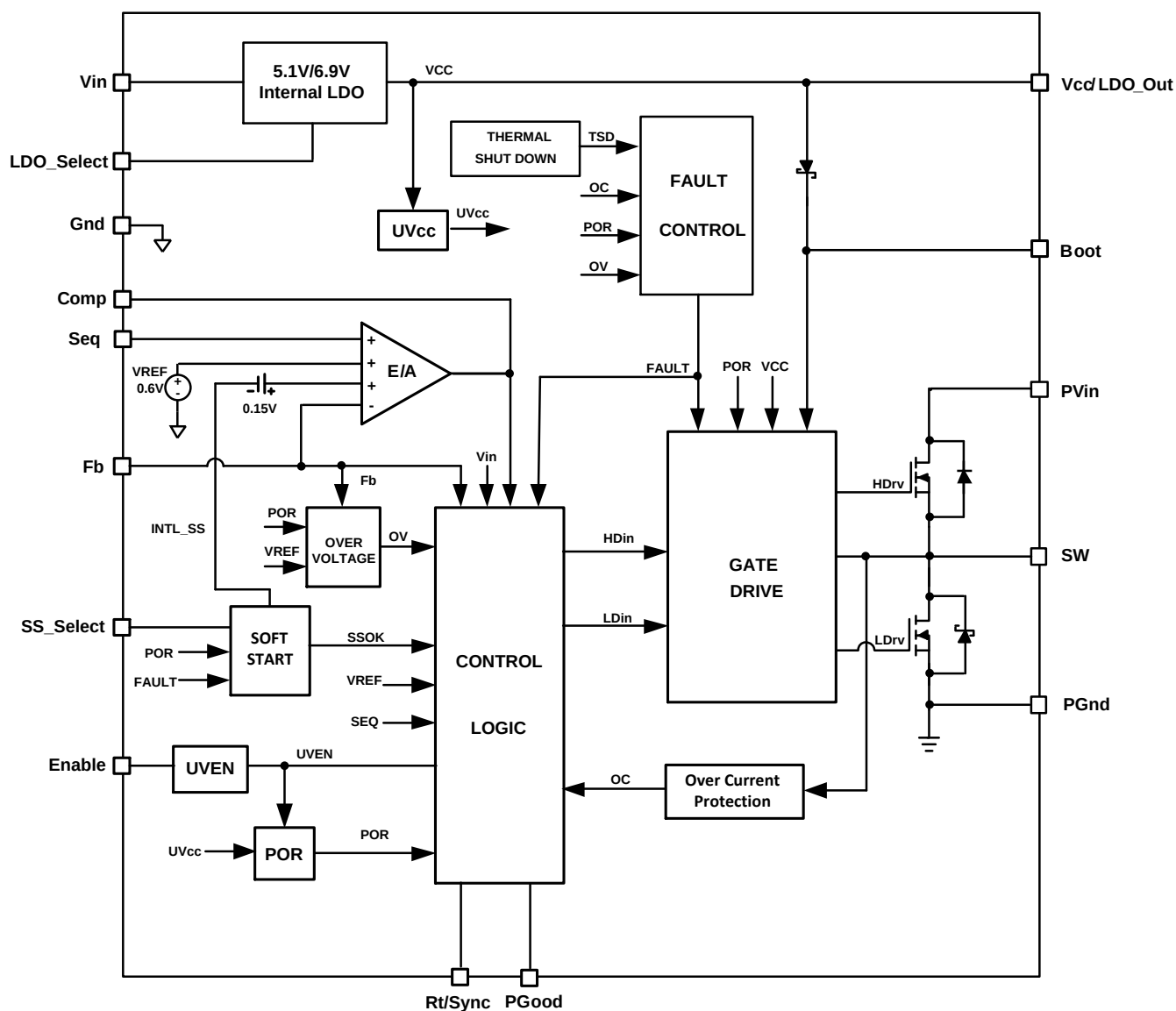


Figure 4 Simplified Block Diagram

## PIN DESCRIPTIONS

| PIN # | PIN NAME         | PIN DESCRIPTION                                                                                                                                                                                                                                                                       |
|-------|------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 1     | Fb               | Inverting input to the error amplifier. This pin is connected directly to the output of the regulator via a resistor divider to set the output voltage and to provide the feedback signal to the error amplifier.                                                                     |
| 2     | N/C              | Should not be connected to other signals on PCB layout. It is internally connected for testing purpose.                                                                                                                                                                               |
| 3     | Comp             | Output of error amplifier. An external resistor and capacitor network is typically connected from this pin to Fb pin to form a loop compensator.                                                                                                                                      |
| 4, 17 | Gnd              | Signal ground for internal reference and control circuitry.                                                                                                                                                                                                                           |
| 5     | Rt/Sync          | Multi-function pin to set the switching frequency. The internal oscillator frequency is set with a resistor between this pin and Gnd. Or synchronization to an external clock by connecting this pin to the external clock signal through a diode.                                    |
| 6     | SS_Select        | Soft start selection pin. Three user selectable soft start time is available: 1.5ms (SS_Select=Vcc), 3ms (SS_Select=Float), 6ms (SS_Select=Gnd)                                                                                                                                       |
| 7     | PGood            | Open-drain power good indication pin. Connect a pull-up resistor from this pin to Vcc.                                                                                                                                                                                                |
| 8     | LDO_Select       | LDO output voltage selection pin. Float gives 5.1V and low 0V (Gnd) gives 6.9V                                                                                                                                                                                                        |
| 9     | V <sub>in</sub>  | Input for internal LDO. A 1.0μF capacitor should be connected between this pin and PGnd. If external supply is connected to Vcc/LDO_out pin, this pin should be shorted to Vcc/LDO_out pin. Connecting this pin to PV <sub>in</sub> can also implement the input voltage feedforward. |
| 10    | Vcc/LDO_Out      | Output of the internal LDO and optional input of an external biased supply voltage. A minimum 2.2μF ceramic capacitor is recommended between this pin and PGnd.                                                                                                                       |
| 11    | PGnd             | Power Ground. This pin serves as a separated ground for the MOSFET drivers and should be connected to the system's power ground plane.                                                                                                                                                |
| 12    | SW               | Switch node. Connected this pin to the output inductor.                                                                                                                                                                                                                               |
| 13    | PV <sub>in</sub> | Input voltage for power stage.                                                                                                                                                                                                                                                        |
| 14    | Boot             | Supply voltage for high side driver, a 100nF capacitor should be connected between this pin and SW pin.                                                                                                                                                                               |
| 15    | Enable           | Enable pin to turn on and off the device. Input voltage monitoring (input UVLO) can also be implemented by connecting this pin to PVin pin through a resistor divider.                                                                                                                |
| 16    | Seq              | Sequence pin to do simultaneous and ratiometric sequencing operation. A resistor divider can be connected from master output to this pin for sequencing mode of operation. If not used, leave it open.                                                                                |
| 17    | Gnd              | Signal ground for internal reference and control circuitry.                                                                                                                                                                                                                           |

## ABSOLUTE MAXIMUM RATINGS

Stresses beyond these listed under “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications are not implied.

|                                                      |                                           |
|------------------------------------------------------|-------------------------------------------|
| PVin, Vin to PGnd (Note 4)                           | -0.3V to 25V                              |
| Vcc/LDO_Out to PGnd (Note 4)                         | -0.3V to 8V (Note 1)                      |
| Boot to PGnd (Note 4)                                | -0.3V to 33V                              |
| SW to PGnd (Note 4)                                  | -0.3V to 25V (DC), -4V to 25V (AC, 100ns) |
| Boot to SW                                           | -0.3V to $V_{CC} + 0.3V$ (Note 2)         |
| PGood, SS_Select to Gnd (Note 4)                     | -0.3V to $V_{CC} + 0.3V$ (Note 2)         |
| Other Input/Output Pins to Gnd (Note 4)              | -0.3V to +3.9V                            |
| PGnd to Gnd                                          | -0.3V to +0.3V                            |
| <b>THERMAL INFORMATION</b>                           |                                           |
| Junction to Ambient Thermal Resistance $\Theta_{JA}$ | 32 °C/W (Note 3)                          |
| Junction to PCB Thermal Resistance $\Theta_{J-PCB}$  | 2 °C/W                                    |
| Storage Temperature Range                            | -55°C to 150°C                            |
| Junction Temperature Range                           | -40°C to 150°C                            |

**Note 1:** Vcc must not exceed 7.5V for Junction Temperature between -10°C and -40°C

**Note 2:** Must not exceed 8V

**Note 3:** Based on IRDC3827 demo board - 2.6"x2.2", 4-layer PCB board using 2 oz. copper on each layer.

**Note 4:** PGnd pin and Gnd pin are connected together.

## ELECTRICAL SPECIFICATIONS

### RECOMMENDED OPERATING CONDITIONS

|                                                                  | SYMBOL                             | MIN | MAX                     | UNITS |
|------------------------------------------------------------------|------------------------------------|-----|-------------------------|-------|
| Input Voltage Range with External V <sub>cc</sub> Note 5, Note 7 | PV <sub>in</sub>                   | 1.0 | 21                      | V     |
| Input Voltage Range with Internal LDO Note 6, Note 7             | V <sub>in</sub> , PV <sub>in</sub> | 5.5 | 21                      |       |
| Supply Voltage Range (Note 6)                                    | V <sub>cc</sub>                    | 4.5 | 7.5                     |       |
| Supply Voltage Range (Note 6)                                    | Boot to SW                         | 4.5 | 7.5                     |       |
| Output Voltage Range                                             | V <sub>o</sub>                     | 0.6 | 0.86 x PV <sub>in</sub> |       |
| Output Current Range                                             | I <sub>o</sub>                     | 0   | 6                       | A     |
| Switching Frequency                                              | F <sub>s</sub>                     | 300 | 1200                    | kHz   |
| Operating Junction Temperature                                   | T <sub>j</sub>                     | -40 | 125                     | °C    |

**Note 5:** V<sub>in</sub> is connected to V<sub>cc</sub> to bypass the internal LDO.

**Note 6:** V<sub>in</sub> is connected to PV<sub>in</sub>. For single-rail applications with PV<sub>in</sub>=V<sub>in</sub>= 4.5V-5.5V, please refer to the application information in the section of User Selectable Internal LDO and the section of Over Current Protection.

**Note 7:** Maximum SW node voltage should not exceed 25V.

### ELECTRICAL CHARACTERISTICS

Unless otherwise specified, these specifications apply over, 5.5V < V<sub>in</sub> = PV<sub>in</sub> < 21V, 0°C < T<sub>j</sub> < 125°C, LDO\_Select=Gnd, SS\_Select=Float. Typical values are specified at T<sub>a</sub> = 25°C.

| PARAMETER                         | SYMBOL                | CONDITIONS                                                                                                                                  | MIN | TYP  | MAX | UNITS |
|-----------------------------------|-----------------------|---------------------------------------------------------------------------------------------------------------------------------------------|-----|------|-----|-------|
| <b>Power Stage</b>                |                       |                                                                                                                                             |     |      |     |       |
| Power Losses                      | P <sub>LOSS</sub>     | PV <sub>in</sub> =V <sub>in</sub> = 12V, V <sub>o</sub> =1.2V, I <sub>o</sub> = 6A, F <sub>s</sub> =600kHz, L=1.0uH, LDO_Select=Gnd. Note 8 |     | 1.1  |     | W     |
|                                   |                       | PV <sub>in</sub> =V <sub>in</sub> =12V, V <sub>o</sub> =1.2V, I <sub>o</sub> =6A, F <sub>s</sub> =600kHz, L=1.0uH, LDO_Select=Float. Note 8 |     | 1.3  |     |       |
| Top Switch R <sub>DS(ON)</sub>    | R <sub>DS(on)-T</sub> | V <sub>BOOT</sub> -V <sub>sw</sub> =5.1V, I <sub>o</sub> = 6A, T <sub>j</sub> = 25°C                                                        |     | 21   | 29  | mΩ    |
|                                   |                       | V <sub>BOOT</sub> -V <sub>sw</sub> =6.9V, I <sub>o</sub> = 6A, T <sub>j</sub> = 25°C                                                        |     | 16   | 22  |       |
| Bottom Switch R <sub>DS(ON)</sub> | R <sub>DS(on)-B</sub> | V <sub>cc</sub> = 5.1V, I <sub>o</sub> = 6A, T <sub>j</sub> = 25°C                                                                          |     | 21.4 | 30  |       |
|                                   |                       | V <sub>cc</sub> = 6.9V, I <sub>o</sub> = 6A, T <sub>j</sub> = 25°C                                                                          |     | 16.8 | 23  |       |
| Bootstrap Diode Forward Voltage   | V <sub>D</sub>        | I(Boot) = 10mA                                                                                                                              | 180 | 260  | 470 | mV    |
| SW Leakage Current                |                       | V <sub>sw</sub> = 0V, Enable = 0V                                                                                                           |     |      | 1   | μA    |
|                                   |                       | V <sub>sw</sub> = 0V, Enable = High, V <sub>SEQ</sub> =0V                                                                                   |     |      | 1   | μA    |
| Dead Band Time                    | T <sub>D</sub>        | Note 8                                                                                                                                      |     | 10   |     | ns    |

**ELECTRICAL CHARACTERISTICS (CONTINUED)**

Unless otherwise specified, these specifications apply over,  $5.5V < V_{in} = PV_{in} < 21V$ ,  $0^{\circ}C < T_J < 125^{\circ}C$ , LDO\_Select=Gnd, SS\_Select=Float. Typical values are specified at  $T_a = 25^{\circ}C$ .

| PARAMETER                     | SYMBOL                   | CONDITIONS                                                                                     | MIN  | TYP   | MAX  | UNITS            |
|-------------------------------|--------------------------|------------------------------------------------------------------------------------------------|------|-------|------|------------------|
| Supply Current                |                          |                                                                                                |      |       |      |                  |
| Vin Supply Current (standby)  | I <sub>in(Standby)</sub> | EN = Low, No Switching                                                                         |      |       | 200  | μA               |
| Vin Supply Current (dynamic)  | I <sub>in(Dyn)</sub>     | EN = High, F <sub>s</sub> = 600kHz, V <sub>in</sub> = PV <sub>in</sub> = 21V, LDO_Select=Gnd   |      | 10    | 13   | mA               |
|                               |                          | EN = High, F <sub>s</sub> = 600kHz, V <sub>in</sub> = PV <sub>in</sub> = 21V, LDO_Select=Float |      | 8     | 11   |                  |
| V <sub>cc</sub> /LDO_Out      |                          |                                                                                                |      |       |      |                  |
| Output Voltage                | V <sub>cc</sub>          | V <sub>in(min)</sub> = 5.5V, I <sub>o</sub> = 0-30mA, Cload =2.2uF, LDO_Select=Float           | 4.75 | 5.1   | 5.4  | V                |
|                               |                          | V <sub>in(min)</sub> = 7.3V, I <sub>o</sub> = 0-30mA, Cload = 2.2uF, LDO_Select=Gnd            | 6.5  | 6.9   | 7.2  |                  |
| LDO_Select Input bias Current |                          | LDO_Select=Gnd                                                                                 |      | 30    | 60   | uA               |
| LDO Dropout Voltage           | V <sub>cc_drop</sub>     | V <sub>in</sub> =6.5V,I <sub>o</sub> =30mA, Cload=2.2uF, LDO_Select=Gnd                        |      |       | 0.7  | V                |
|                               |                          | V <sub>in</sub> =4.7V,I <sub>o</sub> =25mA, Cload=2.2uF, LDO_Select=Float                      |      |       | 0.7  |                  |
| Short Circuit Current         | I <sub>short</sub>       | LDO_Select=Gnd                                                                                 |      | 70    |      | mA               |
| Oscillator                    |                          |                                                                                                |      |       |      |                  |
| Rt Voltage                    | V <sub>Rt</sub>          |                                                                                                |      | 1.0   |      | V                |
| Frequency Range               | F <sub>s</sub>           | Rt = 80.6kΩ                                                                                    | 270  | 300   | 330  | kHz              |
|                               |                          | Rt = 39.2kΩ                                                                                    | 540  | 600   | 660  |                  |
|                               |                          | Rt = 19.1kΩ                                                                                    | 1080 | 1200  | 1320 |                  |
| Ramp Amplitude                | V <sub>ramp</sub>        | V <sub>in</sub> = 7.3V, Vin slew rate max = 1V/μs, Note 8                                      |      | 1.095 |      | V <sub>p-p</sub> |
|                               |                          | V <sub>in</sub> = 12V, Vin slew rate max = 1V/μs, Note 8                                       |      | 1.80  |      |                  |
|                               |                          | V <sub>in</sub> = 21V, Vin slew rate max = 1V/μs, Note 8                                       |      | 3.15  |      |                  |
|                               |                          | V <sub>in</sub> =V <sub>cc</sub> =5V, For external V <sub>cc</sub> operation, Note 8           |      | 0.75  |      |                  |

**ELECTRICAL CHARACTERISTICS (CONTINUED)**

Unless otherwise specified, these specifications apply over,  $5.5V < V_{in} = PV_{in} < 21V$ ,  $0^{\circ}C < T_J < 125^{\circ}C$ , LDO\_Select=Gnd, SS\_Select=Float. Typical values are specified at  $T_a = 25^{\circ}C$ .

| PARAMETER                              | SYMBOL                    | CONDITIONS                                                       | MIN   | TYP  | MAX   | UNITS |
|----------------------------------------|---------------------------|------------------------------------------------------------------|-------|------|-------|-------|
| Ramp Offset                            |                           | Note 8                                                           |       | 0.16 |       | V     |
| Minimum Pulse Width                    | T <sub>min(ctrl)</sub>    | Note 8                                                           |       |      | 60    | ns    |
| Maximum Duty Cycle                     | D <sub>max</sub>          | F <sub>s</sub> = 300kHz, V <sub>in</sub> =PV <sub>in</sub> = 12V | 86    |      |       | %     |
| Fixed Off Time                         | T <sub>off</sub>          | Note 8                                                           |       | 200  | 250   | ns    |
| Sync Frequency Range                   | F <sub>sync</sub>         |                                                                  | 270   |      | 1320  | kHz   |
| Sync Pulse Duration                    | T <sub>sync</sub>         |                                                                  | 100   | 200  |       | ns    |
| Sync Level Threshold                   | High                      |                                                                  | 3     |      |       | V     |
|                                        | Low                       |                                                                  |       |      | 0.6   |       |
| Error Amplifier                        |                           |                                                                  |       |      |       |       |
| Input Offset Voltage                   |                           | V <sub>FB</sub> – V <sub>SEQ</sub> , V <sub>SEQ</sub> =0.3V      | -3    |      | +3    | %     |
| Input Bias Current (V <sub>FB</sub> )  | I <sub>FB</sub> (E/A)     |                                                                  | -1    |      | +1    | μA    |
| Input Bias Current (V <sub>SEQ</sub> ) | I <sub>SEQ</sub> (E/A)    |                                                                  | 0     |      | +4    |       |
| Sink Current                           | I <sub>sink</sub> (E/A)   |                                                                  | 0.4   | 0.85 | 1.2   | mA    |
| Source Current                         | I <sub>source</sub> (E/A) |                                                                  | 4     | 7.5  | 11    | mA    |
| Slew Rate                              | SR                        | Note 8                                                           | 7     | 12   | 20    | V/μs  |
| Gain-Bandwidth Product                 | GBWP                      | Note 8                                                           | 20    | 30   | 40    | MHz   |
| DC Gain                                | Gain                      | Note 8                                                           | 100   | 110  | 120   | dB    |
| Maximum Output Voltage                 | V <sub>max</sub> (E/A)    |                                                                  | 1.7   | 2.0  | 2.3   | V     |
| Minimum Output Voltage                 | V <sub>min</sub> (E/A)    |                                                                  |       |      | 100   | mV    |
| Common Mode Input Voltage              |                           |                                                                  | 0     |      | 1.2   | V     |
| Reference Voltage (V <sub>REF</sub> )  |                           |                                                                  |       |      |       |       |
| Feedback Voltage                       | V <sub>FB</sub>           | LDO_Select= Gnd                                                  |       | 0.6  |       | V     |
|                                        |                           | LDO_Select= Float                                                |       | 0.6  |       |       |
| Accuracy                               |                           | 0°C < T <sub>j</sub> < 70°C                                      | -0.6  |      | +0.6  | %     |
|                                        |                           | -40°C < T <sub>j</sub> < 125°C ; Note 9                          | -1.2  |      | +1.2  |       |
| Soft Start                             |                           |                                                                  |       |      |       |       |
| Soft Start Ramp Rate                   |                           | SS_Select=High                                                   | 0.34  | 0.4  | 0.46  | mV/μs |
|                                        |                           | SS_Select=Float                                                  | 0.17  | 0.2  | 0.23  |       |
|                                        |                           | SS_Select=Gnd                                                    | 0.085 | 0.1  | 0.115 |       |
| SS_Select Input Bias Current           |                           | LDO_Select=Gnd<br>SS_Select=Gnd                                  |       | 40   | 80    | uA    |



**ELECTRICAL CHARACTERISTICS (CONTINUED)**

Unless otherwise specified, these specifications apply over,  $5.5V < V_{in} = PV_{in} < 21V$ ,  $0^{\circ}C < T_J < 125^{\circ}C$ , LDO\_Select=Gnd, SS\_Select=Float. Typical values are specified at  $T_a = 25^{\circ}C$ .

| PARAMETER                           | SYMBOL              | CONDITIONS                                           | MIN  | TYP  | MAX  | UNITS       |
|-------------------------------------|---------------------|------------------------------------------------------|------|------|------|-------------|
| <b>Power Good</b>                   |                     |                                                      |      |      |      |             |
| Power Good Turn on Threshold        | $V_{PG(on)}$        | $V_{FB}$ rising                                      | 85   | 90   | 95   | % $V_{REF}$ |
| Power Good Lower Turn off Threshold | $V_{PG(lower)}$     | $V_{FB}$ falling                                     | 80   | 85   | 90   | % $V_{REF}$ |
| Power Good Turn on Delay            | $TPG(ON)_D$         | $V_{FB}$ rising, see $V_{PG(on)}$                    |      | 2.56 |      | ms          |
| Power Good Upper Turn off Threshold | $V_{PG(upper)}$     | $V_{FB}$ rising                                      | 115  | 120  | 125  | % $V_{REF}$ |
| PGood Comparator Delay              |                     | $V_{FB} < V_{PG(lower)}$ or $V_{FB} > V_{PG(upper)}$ | 1    | 2    | 3.5  | $\mu s$     |
| PGood Voltage Low                   | $PG(voltage)$       | $I_{PGood} = -5mA$                                   |      |      | 0.5  | V           |
| <b>Under-Voltage Lockout</b>        |                     |                                                      |      |      |      |             |
| $V_{cc}$ -Start Threshold           | $V_{CC} UVLO Start$ | $V_{cc}$ rising trip Level                           | 3.9  | 4.1  | 4.3  | V           |
| $V_{cc}$ -Stop Threshold            | $V_{CC} UVLO Stop$  | $V_{cc}$ falling trip Level                          | 3.6  | 3.8  | 4.0  | V           |
| Enable-Start-Threshold              | Enable UVLO Start   | ramping up                                           | 1.14 | 1.2  | 1.26 | V           |
| Enable-Stop-Threshold               | Enable UVLO Stop    | ramping down                                         | 0.95 | 1    | 1.05 |             |
| Enable Leakage Current              | $I_{EN\_LK}$        | Enable = 3.3V                                        |      |      | 1    | $\mu A$     |
| <b>Over-Voltage Protection</b>      |                     |                                                      |      |      |      |             |
| OVP Trip Threshold                  | $OVP\_V_{th}$       | $V_{FB}$ rising                                      | 115  | 120  | 125  | % $V_{REF}$ |
| OVP Comparator Delay                | $T_{OVP\_D}$        |                                                      | 1    | 2    | 3.5  | $\mu s$     |
| <b>Over-Current Protection</b>      |                     |                                                      |      |      |      |             |
| Current Limit                       | $I_{LIMIT}$         | $T_J = 25^{\circ}C$ , LDO_Select=Float               | 6.2  | 7.3  | 8.5  | A           |
|                                     |                     | $T_J = 25^{\circ}C$ , LDO_Select=Gnd                 | 7.9  | 9.3  | 10.8 |             |
| Hiccup Blanking Time                | $T_{BLK\_Hiccup}$   | SS_Select = Vcc, Note 8                              |      | 10   |      | ms          |
|                                     |                     | SS_Select = Float, Note 8                            |      | 20   |      |             |
|                                     |                     | SS_Select = Gnd, Note 8                              |      | 40   |      |             |

**ELECTRICAL CHARACTERISTICS (CONTINUED)**

Unless otherwise specified, these specifications apply over,  $5.5V < V_{in} = PV_{in} < 21V$ ,  $0^{\circ}C < T_J < 125^{\circ}C$ , LDO\_Select=Gnd, SS\_Select=float. Typical values are specified at  $T_a = 25^{\circ}C$ .

| PARAMETER                   | SYMBOL | CONDITIONS                                        | MIN | TYP | MAX | UNITS |
|-----------------------------|--------|---------------------------------------------------|-----|-----|-----|-------|
| Upper Gate Driver           |        |                                                   |     |     |     |       |
| Source Resistance           |        | V <sub>BOOT</sub> -V <sub>SW</sub> = 5.1V, Note 8 |     | 3   |     | Ω     |
| Sink Resistance             |        | V <sub>BOOT</sub> -V <sub>SW</sub> = 5.1V, Note 8 |     | 4   |     |       |
| Lower Gate Driver           |        |                                                   |     |     |     |       |
| Source Resistance           |        | V <sub>CC</sub> = 5.1V, Note 8                    |     | 2   |     | Ω     |
| Sink Resistance             |        | V <sub>CC</sub> = 5.1V, Note 8                    |     | 0.8 |     |       |
| Over-Temperature Protection |        |                                                   |     |     |     |       |
| Thermal Shutdown Threshold  |        | Note 8                                            |     | 145 |     | °C    |
| Hysteresis                  |        | Note8                                             |     | 20  |     |       |

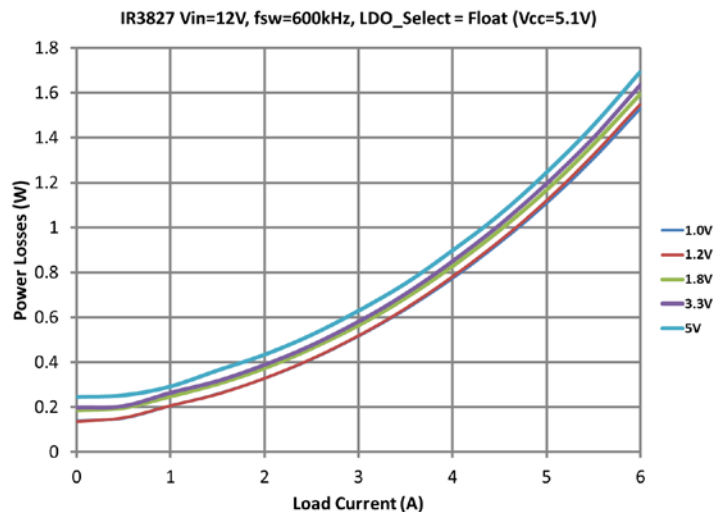
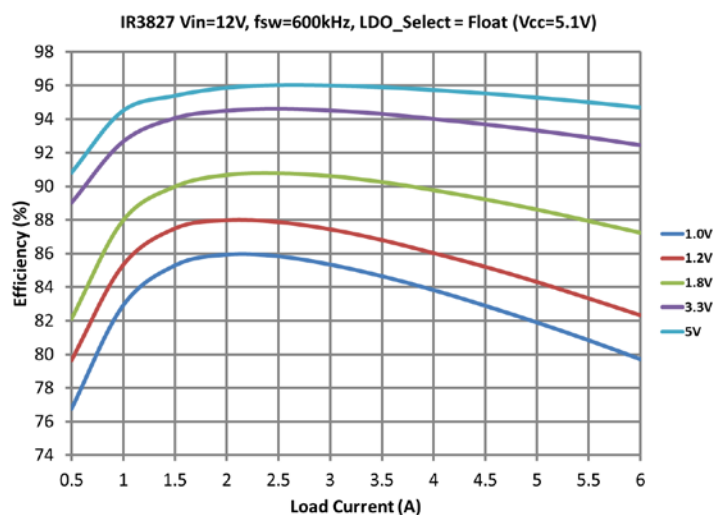
**Note 8:** Guaranteed by design, but not tested in production.

**Note 9:** Cold temperature performance is guaranteed via correlation using statistical quality control. Not tested in production.

## TYPICAL EFFICIENCY AND POWER LOSS CURVES

$P_{V_{in}} = 12V$ ,  $V_{CC} = \text{Internal LDO}$ ,  $LDO\_Select = \text{Float}$ ,  $I_O = 0A-6A$ ,  $F_S = 600\text{ kHz}$ , Room Temperature, No Air Flow. Note that the efficiency and power loss curves include the losses of IR3827, the inductor losses and the losses of the input and output capacitors. The table below shows the inductors used for each of the output voltages in the efficiency measurement.

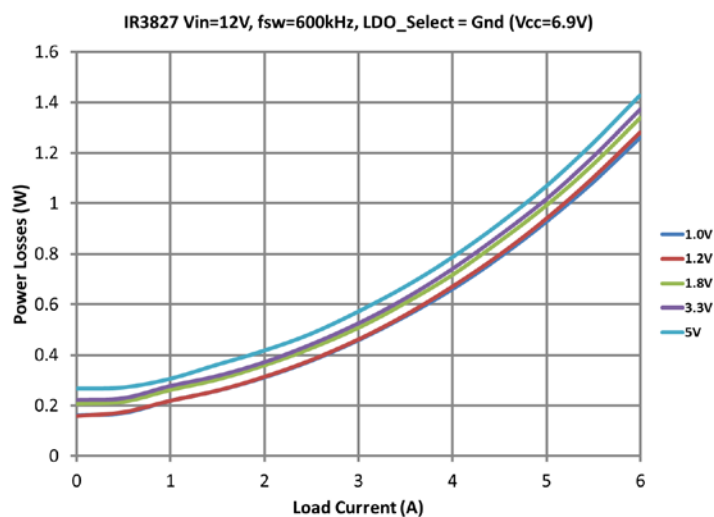
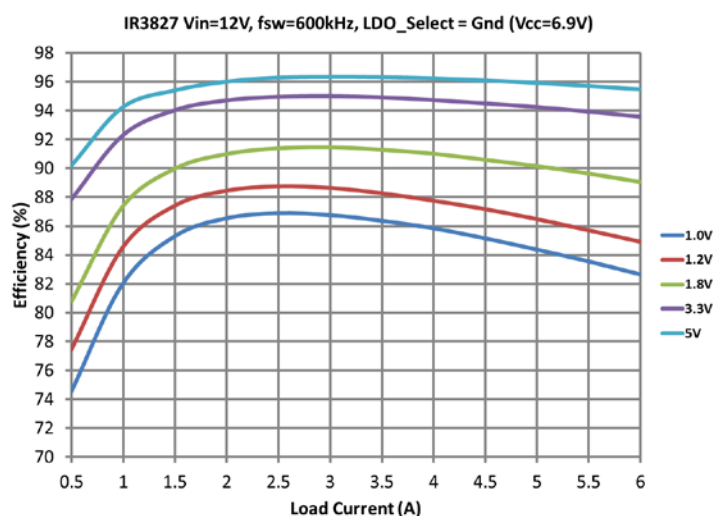
| VOUT (V) | LOUT ( $\mu H$ ) | P/N                          | DCR ( $m\Omega$ ) |
|----------|------------------|------------------------------|-------------------|
| 1.0      | 0.82             | SPM6550T-R82M (TDK)          | 4.2               |
| 1.2      | 1.0              | SPM6550T-1R0M (TDK)          | 4.7               |
| 1.8      | 1.0              | SPM6550T-1R0M (TDK)          | 4.7               |
| 3.3      | 2.2              | 7443340220(Wurth Elektronik) | 4.4               |
| 5        | 2.2              | 7443340220(Wurth Elektronik) | 4.4               |



## TYPICAL EFFICIENCY AND POWER LOSS CURVES

$P_{V_{in}} = 12V$ ,  $V_{CC} = \text{Internal LDO}$ ,  $LDO\_Select = Gnd$ ,  $I_o = 0A-6A$ ,  $F_S = 600\text{ kHz}$ , Room Temperature, No Air Flow. Note that the efficiency and power loss curves include the losses of IR3827, the inductor losses and the losses of the input and output capacitors. The table below shows the inductors used for each of the output voltages in the efficiency measurement.

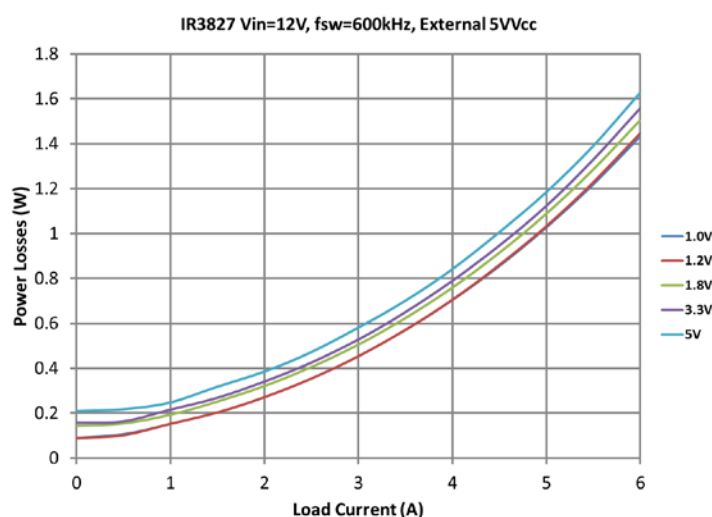
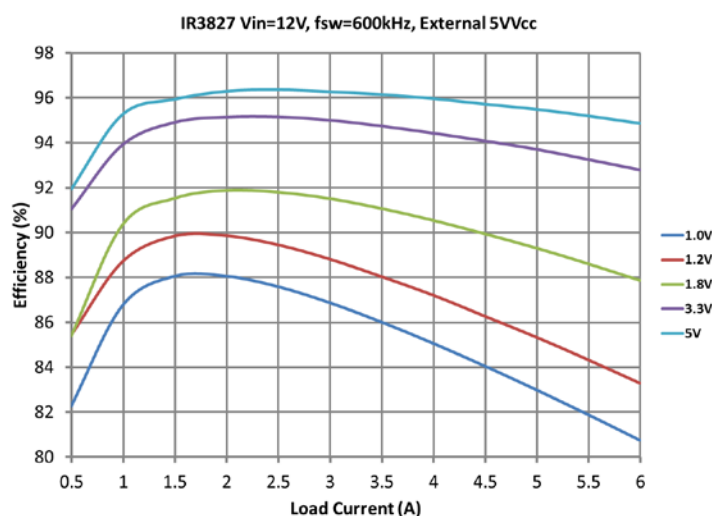
| VOUT (V) | LOUT ( $\mu H$ ) | P/N                          | DCR ( $m\Omega$ ) |
|----------|------------------|------------------------------|-------------------|
| 1.0      | 0.82             | SPM6550T-R82M (TDK)          | 4.2               |
| 1.2      | 1.0              | SPM6550T-1R0M (TDK)          | 4.7               |
| 1.8      | 1.0              | SPM6550T-1R0M (TDK)          | 4.7               |
| 3.3      | 2.2              | 7443340220(Wurth Elektronik) | 4.4               |
| 5        | 2.2              | 7443340220(Wurth Elektronik) | 4.4               |



## TYPICAL EFFICIENCY AND POWER LOSS CURVES

$P_{V_{in}} = 12V$ ,  $V_{CC} = \text{External } 5V$ ,  $I_O = 0A-6A$ ,  $F_S = 600 \text{ kHz}$ , Room Temperature, No Air Flow. Note that the efficiency and power loss curves include the losses of IR3827, the inductor losses and the losses of the input and output capacitors. The table below shows the inductors used for each of the output voltages in the efficiency measurement.

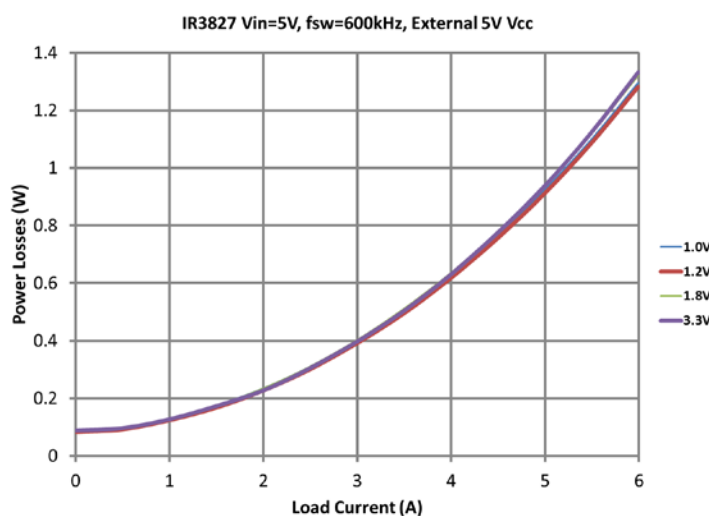
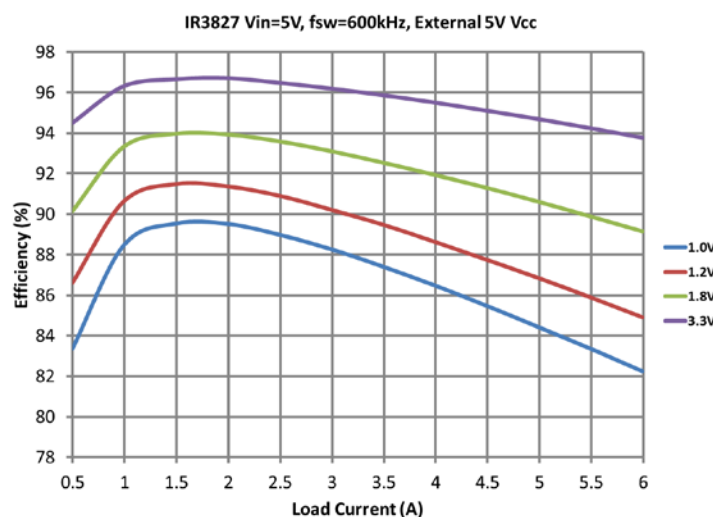
| VOUT (V) | LOUT ( $\mu H$ ) | P/N                          | DCR ( $m\Omega$ ) |
|----------|------------------|------------------------------|-------------------|
| 1.0      | 0.82             | SPM6550T-R82M (TDK)          | 4.2               |
| 1.2      | 1.0              | SPM6550T-1R0M (TDK)          | 4.7               |
| 1.8      | 1.0              | SPM6550T-1R0M (TDK)          | 4.7               |
| 3.3      | 2.2              | 7443340220(Wurth Elektronik) | 4.4               |
| 5        | 2.2              | 7443340220(Wurth Elektronik) | 4.4               |



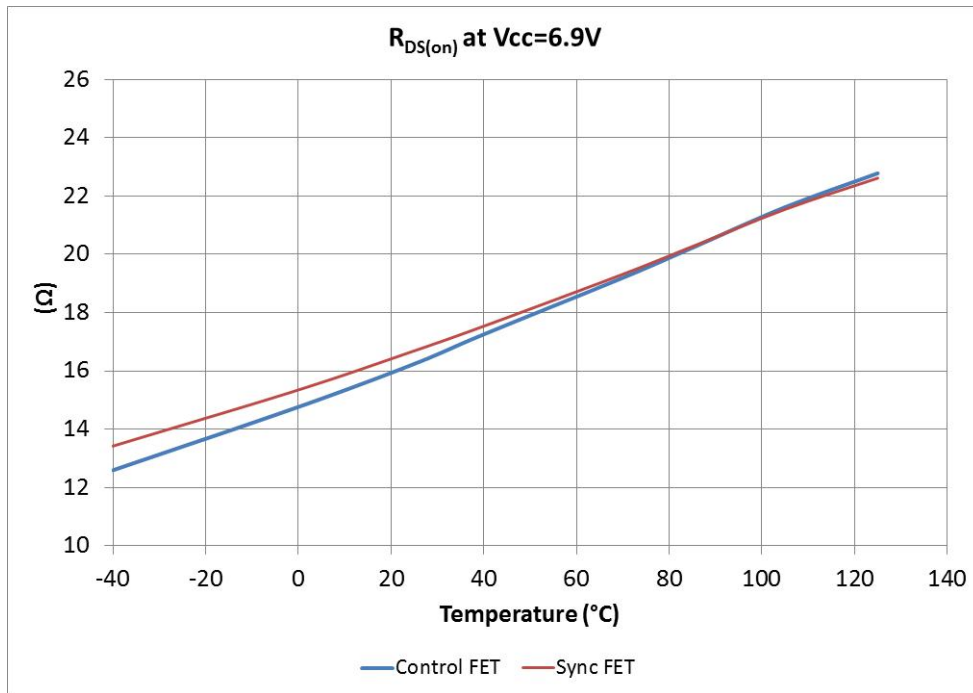
## TYPICAL EFFICIENCY AND POWER LOSS CURVES

$PV_{in} = V_{in} = V_{CC} = 5V$ ,  $I_O = 0A-6A$ ,  $F_S = 600\text{ kHz}$ , Room Temperature, No Air Flow. Note that the efficiency and power loss curves include the losses of IR3827, the inductor losses and the losses of the input and output capacitors. The table below shows the inductors used for each of the output voltages in the efficiency measurement.

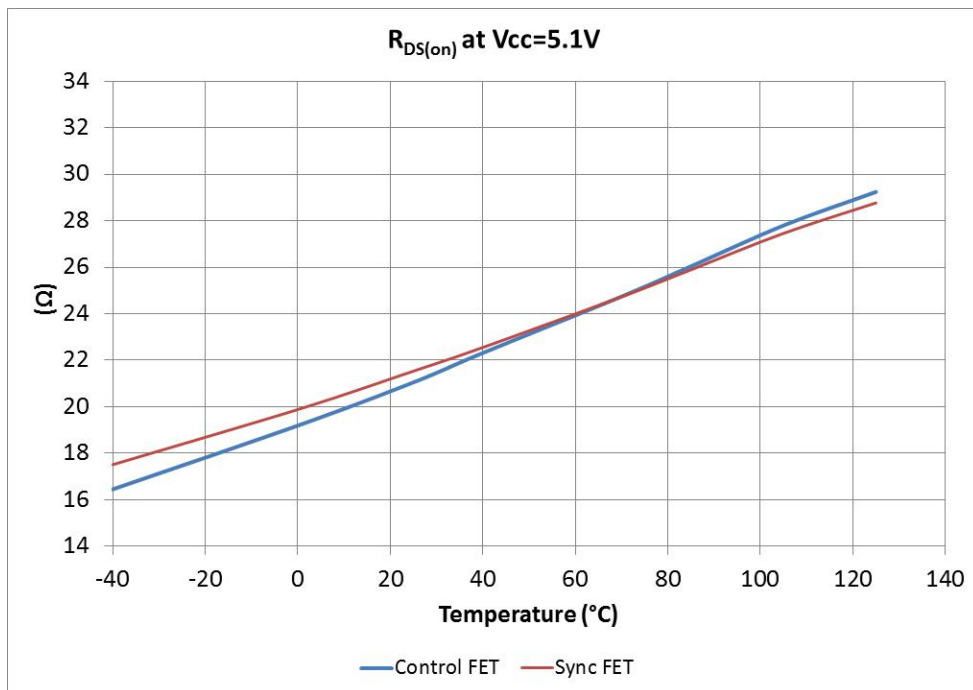
| VOUT (V) | LOUT ( $\mu\text{H}$ ) | P/N                      | DCR ( $\text{m}\Omega$ ) |
|----------|------------------------|--------------------------|--------------------------|
| 1.0      | 0.68                   | PCMB065T- R68MS (Cyntec) | 3.9                      |
| 1.2      | 0.82                   | SPM6550T-R82M(TDK)       | 4.2                      |
| 1.8      | 0.82                   | SPM6550T-R82M(TDK)       | 4.7                      |
| 3.3      | 1.0                    | SPM6550T-1R0M(TDK)       | 4.7                      |



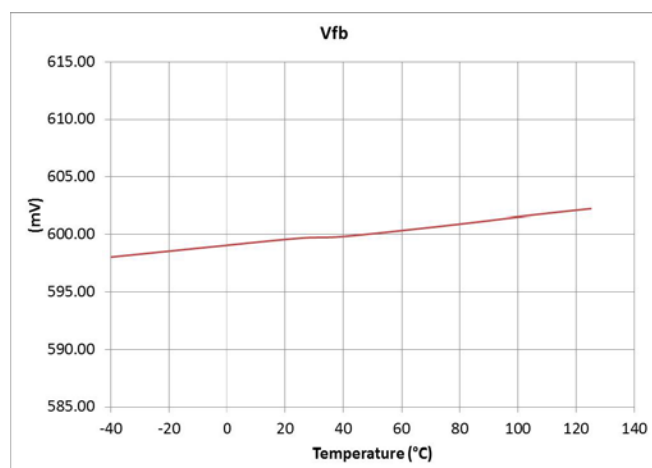
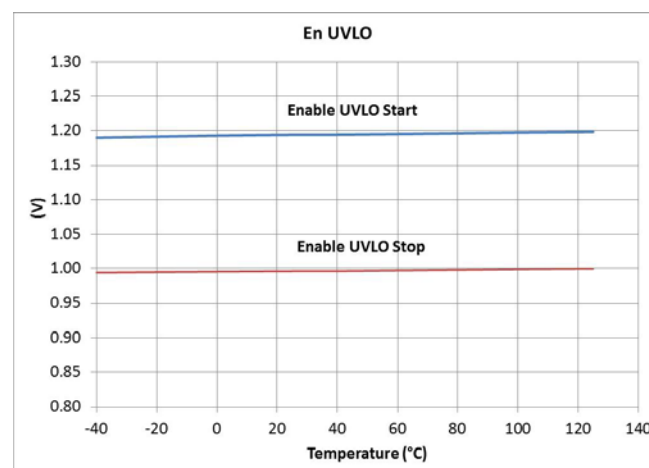
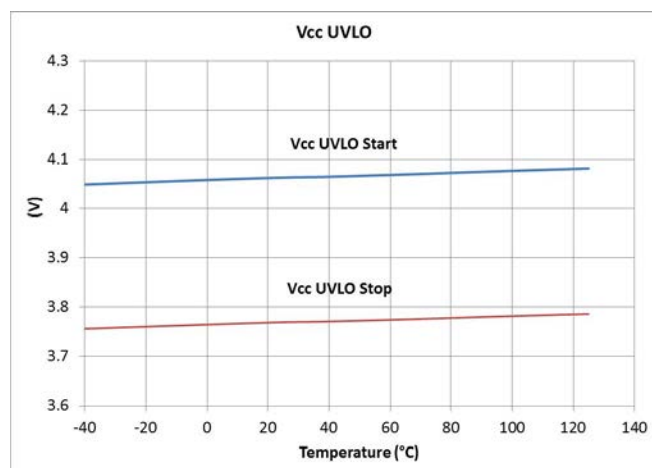
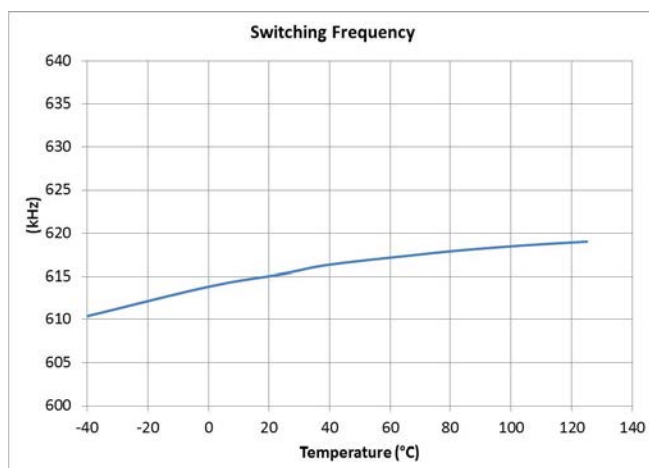
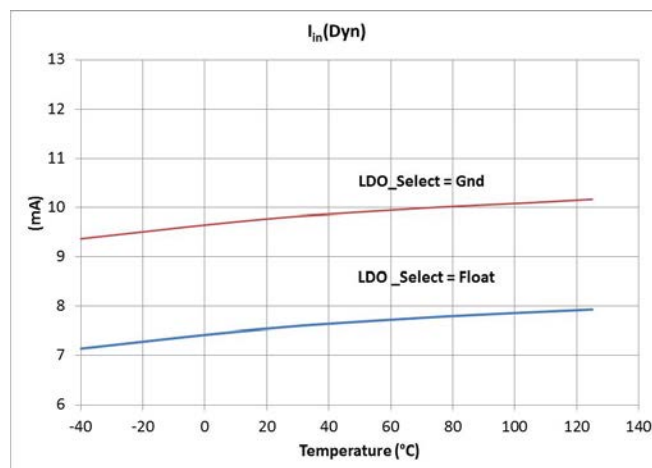
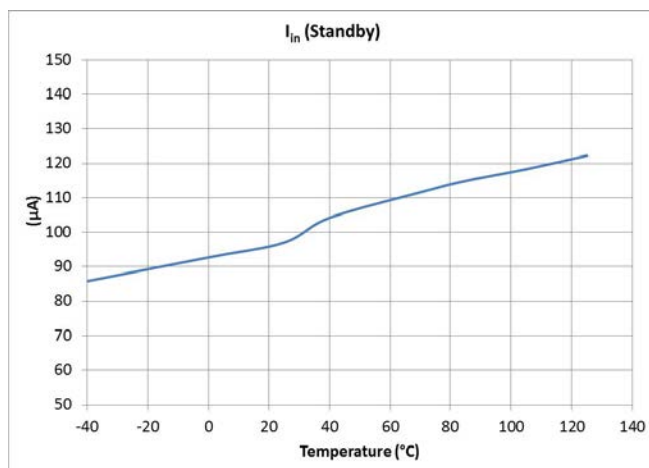
## $R_{DS(on)}$ OF MOSFETS OVER TEMPERATURE AT $V_{CC}=6.9V$



## $R_{DS(on)}$ OF MOSFETS OVER TEMPERATURE AT $V_{CC}=5.1V$

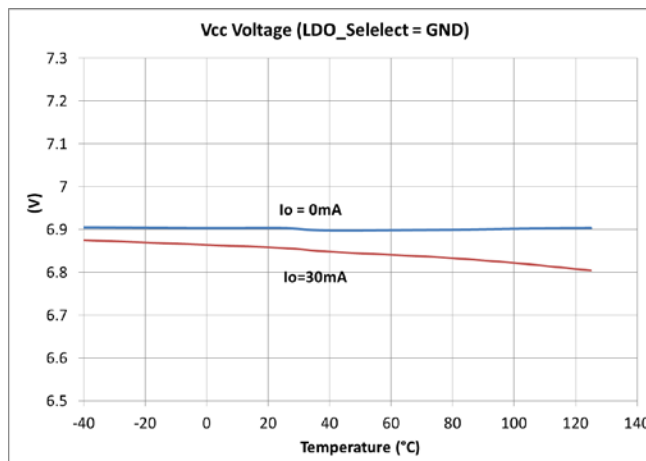
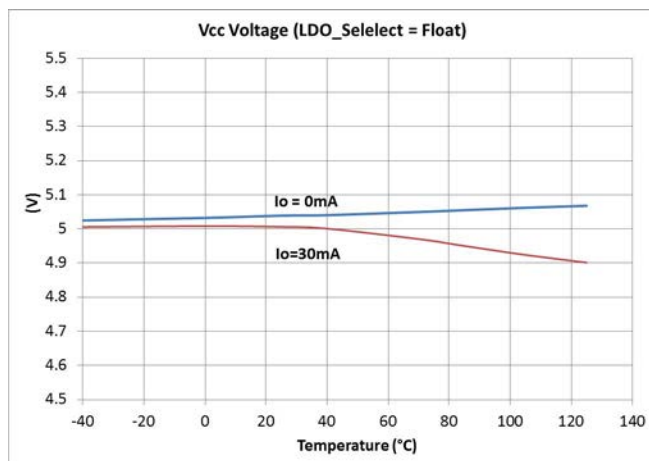
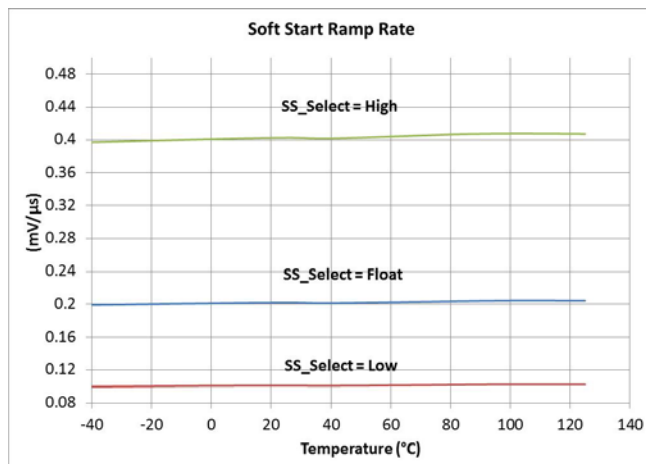
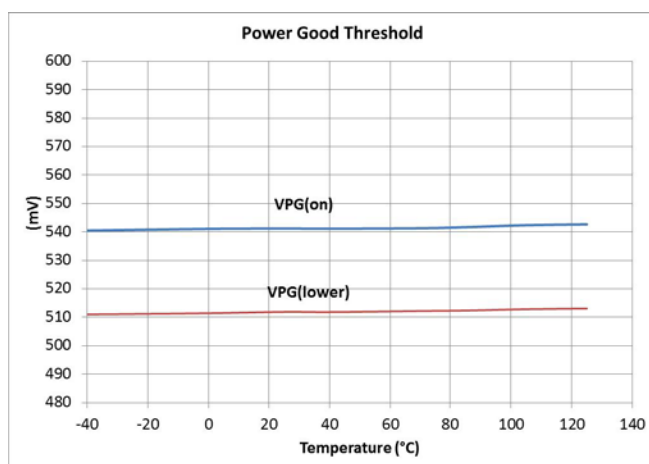
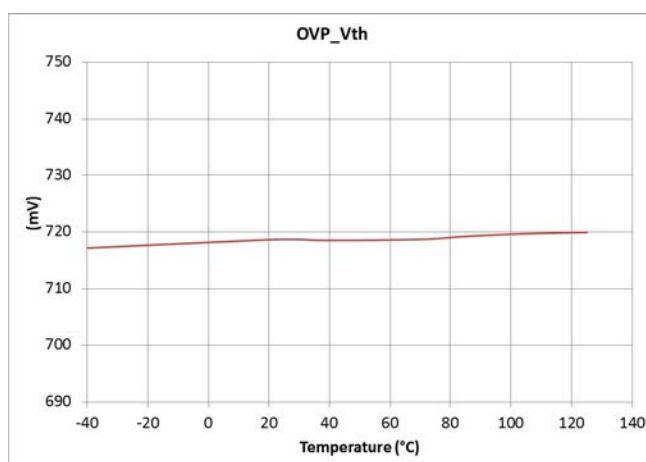
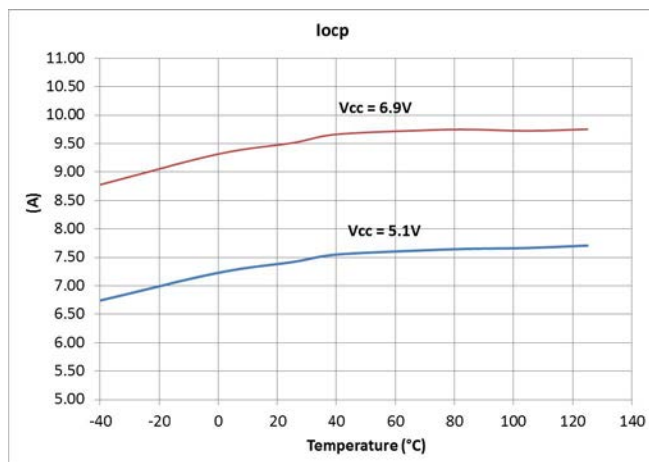


# TYPICAL OPERATING CHARACTERISTICS (-40°C TO +125°C)





# TYPICAL OPERATING CHARACTERISTICS (-40°C TO +125°C)



## THEORY OF OPERATION

### DESCRIPTION

The IR3827 SupIRBuck™ is a 6A easy-to-use, fully integrated and highly efficient synchronous Buck regulator intended for Point-Of-Load (POL) applications. It includes two IR HEXFETs with low  $R_{DS(on)}$ . The bottom FET has an integrated monolithic schottky diode in place of a conventional body diode.

The IR3827 provides precisely regulated output voltage programmed via two external resistors from  $0.6V$  to  $0.86 \times V_{in}$ . It uses voltage mode control employing a proprietary PWM modulator with input voltage feedforward. That provides excellent noise immunity, easy loop compensation design, and good line transient response.

The IR3827 has a user-selectable internal Low Dropout (LDO) Regulator, allowing single supply operation without resorting to an external bias supply voltage. To further improve the efficiency, the internal LDO can be bypassed. Instead an external bias supply can be used. This feature allows the input bus voltage range extended to  $1.0V$ .

The IR3827 features programmable switching frequency from  $300kHz$  to  $1.2MHz$ , three selectable soft-start time, and smooth synchronization to an external clock. The other important functions include thermally compensated over current protection, output over voltage protection and thermal shut-down, etc.

### VOLTAGE LOOP COMPESNATION DESIGN

The IR3827 uses PWM voltage mode control. The output voltage of the POL, sensed by a resistor divider, is fed into an internal Error Amplifier (E/A). The output of the E/R is then compared to an internal ramp voltage to determine the pulse width of the gate signal for the control FET. The amplitude of the ramp voltage is proportional to  $V_{in}$  so that the bandwidth of the voltage loop remains almost constant for different input voltages. This feature is called input voltage feedforward. It allows the feedback loop design independent of the input voltage. Please refer to the next section for more information.

A RC network has to be connected between the FB pin and the COMP pin to form a feedback compensator. The goal of the compensator design is to achieve a high control bandwidth with a phase margin of  $45^\circ$  or above. The high control bandwidth is beneficial for the loop dynamic response, which helps to reduce the number of output capacitors, PCB size and the cost. A phase margin of  $45^\circ$  or higher is desired to ensure the system stability. For most applications, a gain margin of  $-10dB$  or higher is preferred to accommodate component variations and to eliminate jittering/noise. The proprietary PWM modulator in IR3827 significantly reduces the PWM jittering, allowing the control bandwidth in the range of  $1/10^{th}$  to  $1/5^{th}$  of the switching frequency.

Two types of compensators are commonly used: Type II (PI) and Type III (PID), as shown in Figure 5. The selection of the compensation type is dependent on the ESR of the output capacitors. Electrolytic capacitors have relatively higher ESR. If the ESR pole is located at the frequency lower than the cross-over frequency,  $F_C$ , the ESR pole will help to boost the phase margin. Thus a type II compensator can be used. For the output capacitors with lower ESR such as ceramic capacitors, type III compensation is often desired.

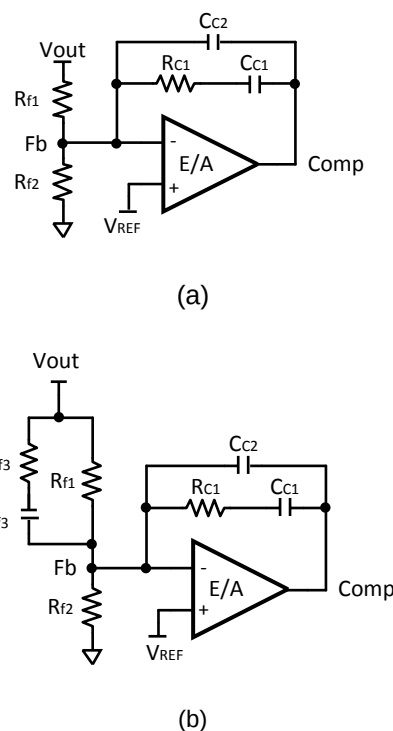


Figure 5 Loop Compensator (a) Type II, (b) Type III

Table 1 lists the compensation selection for different types of output capacitors.

For more detailed design guideline of voltage loop compensation, please refer to the application note AN-1162, “*Compensation Design Procedure for Buck Converter with Voltage-Mode Error-Amplifier*”. SupBuck design tool is also available at [www.irf.com](http://www.irf.com) providing the reference design based on user’s design requirements.

**TABLE 1 RECOMMENDED COMPENSATION TYPE**

| COMPENSATOR      | LOCATION OF CROSS-OVER FREQUENCY | TYPE OF OUTPUT CAPACITORS     |
|------------------|----------------------------------|-------------------------------|
| Type II (PI)     | $F_{LC} < F_{ESR} < F_0 < F_S/2$ | Electrolytic, POS-CAP, SP-CAP |
| Type III-A (PID) | $F_{LC} < F_0 < F_{ESR} < F_S/2$ | POS-CAP, SP-CAP               |
| Type III-B (PID) | $F_{LC} < F_0 < F_S/2 < F_{ESR}$ | Ceramic                       |

$F_{LC}$  is the resonant frequency of the output LC filter. It is often referred to as double pole.

$$F_{LC} = \frac{1}{2 \times \pi \sqrt{L_o \times C_o}}$$

$F_{ESR}$  is the ESR zero of the output capacitor.

$$F_{ESR} = \frac{1}{2\pi \times ESR \times C_o}$$

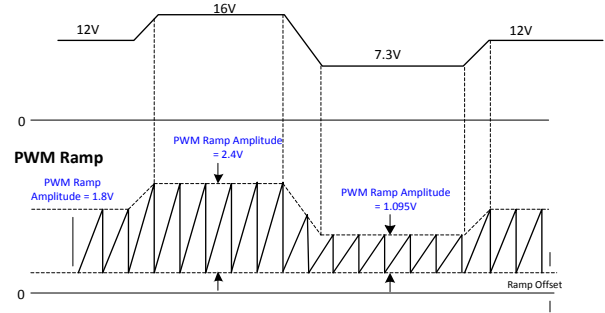
$F_0$  is the cross-over frequency of the closed voltage loop and  $F_S$  is the switching frequency.

## INPUT VOLTAGE FEEDFORWARD

Input voltage feedforward is an important feature, because it can keep the converter stable and preserve its load transient performance when  $V_{in}$  varies in a large range. In IR3827, feedforward function is enabled when  $V_{in}$  pin is connected to  $PV_{in}$  pin and  $V_{in} > 5.5V$ . In this case, the internal low dropout (LDO) regulator is used. The PWM ramp amplitude ( $V_{ramp}$ ) is proportionally changed with  $V_{in}$  to maintain the ratio  $V_{in}/V_{ramp}$  almost constant throughout  $V_{in}$  variation range (as shown in Figure 6). Thus, the control loop bandwidth and phase margin can be maintained constant. Feed-forward

function can also minimize impact on output voltage from fast  $V_{in}$  change. The maximum  $V_{in}$  slew rate is within  $1V/\mu s$ .

If an external bias voltage is used as  $V_{CC}$ ,  $V_{in}$  pin should be connected to  $V_{CC}/LDO\_out$  pin instead of  $PV_{in}$  pin. Then the feedforward function is disabled. The control loop compensation might need to be adjusted.



**Figure 6 Timing Diagram for Input Feedforward**

## UNDER-VOLTAGE LOCKOUT AND POR

The Under-Voltage Lockout (UVLO) circuit monitors the voltage of  $V_{CC}/LDO\_Output$  pin and the Enable pin. It assures that the MOSFET driver outputs remain off whenever either of these two signals is below the set thresholds. Normal operation resumes once both  $V_{CC}/LDO\_Output$  and  $En$  voltages rise above their thresholds.

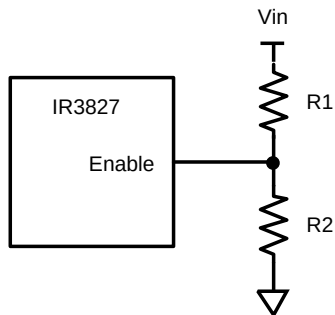
The POR (Power On Ready) signal is generated when all these signals reach the valid logic level (see system block diagram). When the POR is asserted, the soft start sequence starts (see soft start section).

## ENABLE/EXTERNAL PVIN MONITOR

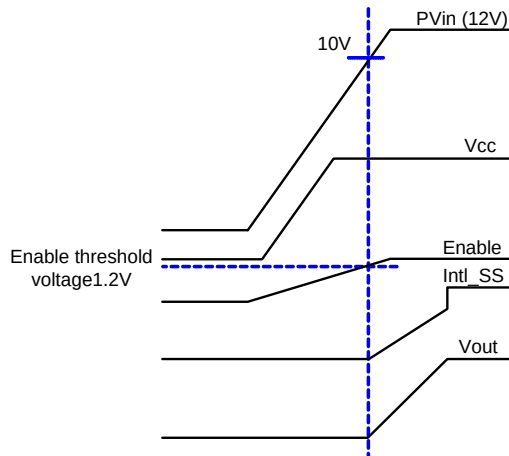
The IR3827 has an Enable function providing another level of flexibility for start-up. The Enable pin has a precise threshold which is internally monitored by Under-Voltage Lockout (UVLO) circuit. If the voltage at Enable pin is below its UVLO threshold, both high-side and low-side FETs are off. When Enable pin is below its UVLO, Over-Voltage Protection (OVP) is disabled, and PGood stays low.

The Enable pin should not be left floating. A pull-down resistor in the range of several kilo ohms is recommended to connect between the Enable Pin and Gnd.

In addition to logical inputs, the Enable pin can be used to implement precise input voltage UVLO. As shown in Figure 7, the input of the Enable pin is derived from the  $PV_{in}$  voltage by a set of resistive divider, R1 and R2. By selecting different divider ratios, users can program the UVLO threshold voltage. The bus voltage UVLO is a very desirable feature. It prevents the IR3827 from regulating at  $PV_{in}$  lower than the desired voltage level. Figure 8 shows the start-up waveform with the input UVLO voltage set at 10V.



**Figure 7 Implementation of Input Under-Voltage Lockout (UVLO) using Enable Pin**



**Figure 8 Illustration of start-up with  $PV_{in}$  UVLO threshold voltage of 10V. The internal soft-start is used in this case.**

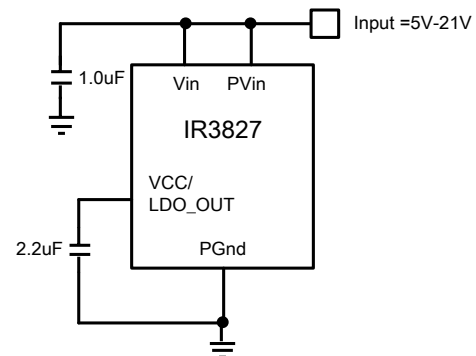
## USER SELECTABLE INTERNAL LDO

The IR3827 has an internal Low Dropout Regulator (LDO), offering two LDO voltage options – 5.1V and 6.9V. 5.1V  $V_{CC}$  voltage results in higher light load efficiency due to the lower gate charge loss, while 6.9V  $V_{CC}$  voltage results in higher full load efficiency due to less conduction loss. User can select the desired  $V_{CC}$  voltage based on the design target. The selection of the LDO voltage is achieved with LDO\_Select pin, as shown in Table 2. It should be noted that 6.9V  $V_{CC}$  voltage results in faster switching speed and may cause higher voltage spike at the SW node than 5.1V  $V_{CC}$  voltage.

**TABLE 2 CONFIGURATION OF INTERNAL LDO**

| LDO_SELECT | VCC/LDO_OUT |
|------------|-------------|
| Float      | 5.1V        |
| Gnd        | 6.9V        |

The internal LDO is beneficial for single rail (supply) applications, where no external bias supplies will be needed. For these applications,  $V_{in}$  pin should be connected to  $PV_{in}$  and  $V_{CC}/LDO\_Out$  pin is left floating as shown in Figure 9. 1.0 $\mu$ F and 2.2 $\mu$ F ceramic bypass capacitors should be placed close to  $V_{in}$  pin and  $V_{CC}/LDO\_Out$  pin respectively.



**Figure 9 Internally Biased Single-Rail Configuration**

When  $V_{in}$  drops below 5.5V (LDO\_Select = Float), or 7.3V (LDO\_Select = Gnd), the internal LDO enters the dropout mode. Figure 10 shows the  $V_{CC}/LDO\_Out$  voltage for  $V_{in}=PV_{in}=5V$  with switching frequency of 600kHz and 1200kHz respectively. Alternatively, if the input bus voltage,  $PV_{in}$ , is in the range of 4.5V to 7.5V,  $V_{CC}/LDO\_Out$  pin can be

directly connected to the  $PV_{in}$  pin to bypass the internal LDO and therefore to avoid the voltage drop on the internal LDO. This configuration is illustrated in Figure 11.

Figure 12 shows the configuration using an external  $V_{CC}$  voltage. With this configuration, the input voltage range can be extended down to 1.0V. Please note that the input feedforward function is disabled for this configuration. The feedback compensation needs to be adjusted accordingly.

It should be noted as the  $V_{CC}$  voltage decreases, the efficiency and the over current limit will decrease due to the increase of  $R_{DS(ON)}$ . Please refer to the section of the over current protection for more information.

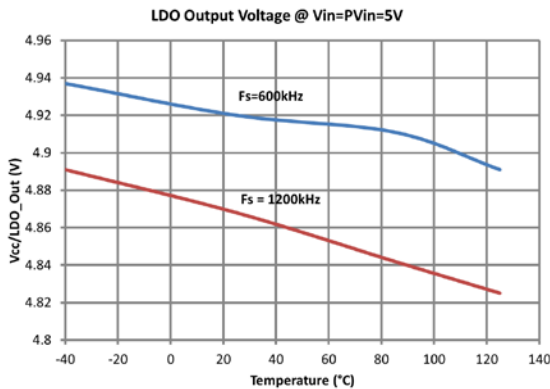


Figure 10 LDO Dropout Voltage at  $V_{in}=PV_{in}=5V$

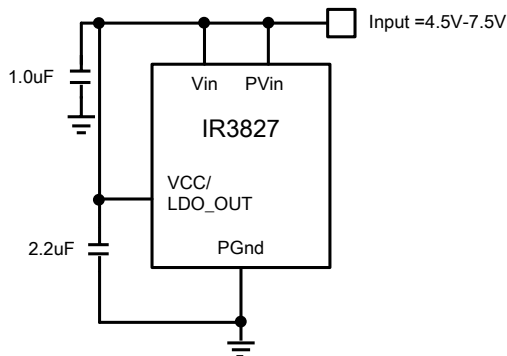


Figure 11 Single-Rail Configuration for 4.5V-7V inputs

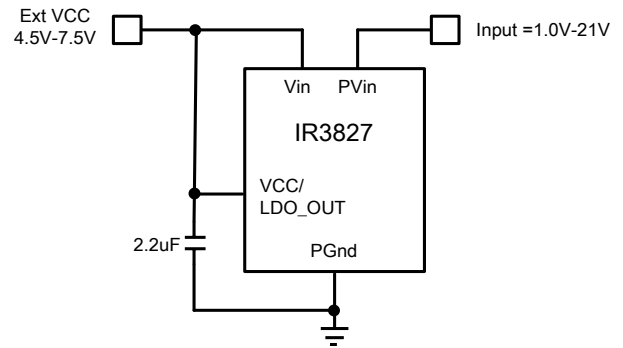


Figure 12 Use External Bias Voltage

## SOFT-START

The IR3827 has an internal digital soft-start circuit to control the output voltage rise time, and to limit the current surge at the start-up. To ensure correct start-up, the soft-start sequence initiates when the Enable and Vcc voltages rise above their UVLO thresholds and generate the Power On Ready (POR) signal. The slew rate of the internal soft-start can be adjusted externally with SS\_Select pin, as shown in Table 3.

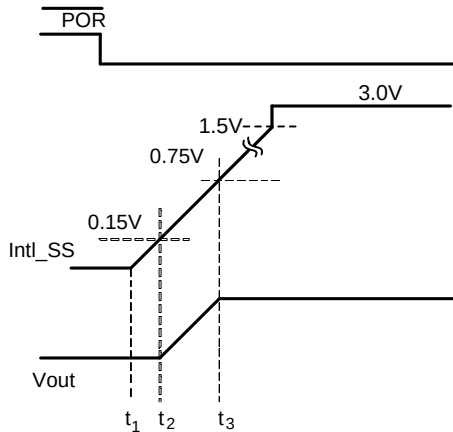
Table 3 User Selectable Soft-Start Time

| SS_Select | Slew Rate (mV/ $\mu$ s) | Soft-Start Time (ms) |
|-----------|-------------------------|----------------------|
| Vcc       | 0.4                     | 1.5                  |
| Float     | 0.2                     | 3                    |
| Gnd       | 0.1                     | 6                    |

Figure 13 shows the waveforms during the soft start. The corresponding soft-start time can be calculated as follows.

$$T_{ss} = \frac{0.75V - 0.15V}{SlewRate}$$

It should be noted that during the soft-start the over-current protection (OCP) and over-voltage protection (OVP) is enabled to protect the device for any short circuit or over voltage condition.



**Figure 13 Theoretical start-up waveforms using internal soft-start**

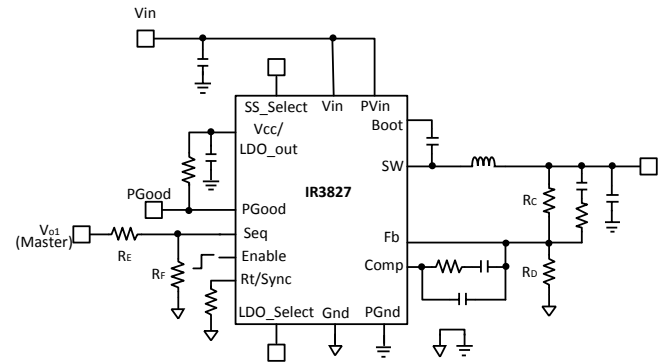
## POWER UP SEQUENCING

The IR3827 provides the simultaneous or ratiometric sequencing function with Seq pin. As shown in the block diagram, the Error-Amplifier (E/A) has three positive inputs. The input with the lowest voltage is used for regulating the output voltage and the other two inputs are ignored. In practice, the voltage of the other two inputs should be about 200mV greater than the low-voltage input so that their effects can completely be ignored. Seq pin is internally biased to 3.3V via a high impedance path. For normal operation, Seq pin is left floating.

In sequencing operation, the voltage at Seq pin,  $V_{SEQ}$ , should be kept to zero until the internal soft-start is finished. Then  $V_{SEQ}$  is ramped up and the feedback voltage,  $V_{FB}$ , follows  $V_{SEQ}$ . When  $V_{SEQ}$  is above 0.6V, the Error-Amplifier switches to  $V_{REF}$  and  $V_{FB}$  starts to follow  $V_{REF}$ . The final  $V_{SEQ}$  voltage after sequencing startup should be between 0.7V ~ 3.3V.

Figure 14 shows the typical application circuit for sequencing operation.  $V_{SEQ}$  is derived from the output of another voltage regulator (Master) through a resistor divider composed of  $R_E$  and  $R_F$ . If the ratio of this resistor divider is equal to that of the feedback resistor divider i.e.  $R_E/R_F = R_C/R_D$ , simultaneous start-up is achieved. That is, the output voltage of the slave follows that of the master until the voltage at the Seq pin of the slave reaches 0.6 V. After  $V_{SEQ}$  of the slave exceeds 0.6V, the internal 0.6V reference voltage of the slave dictates its output. To achieve ratiometric operation,  $R_E/R_F > R_C/R_D$  should

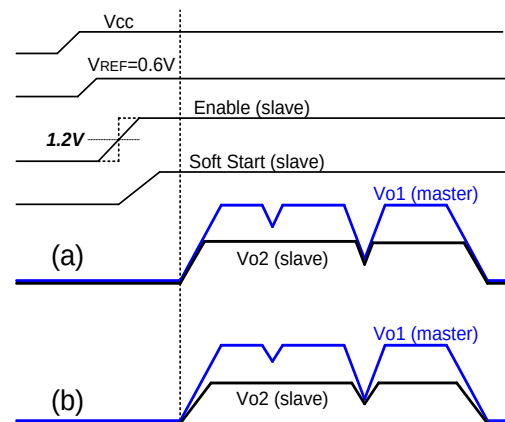
be used. Table 4 summarizes the configurations to achieve simultaneous/ratiometric sequencing operations and normal start-up using the internal soft-start. Figure 15 shows the typical waveforms for sequencing operations.



**Figure 14 Application circuit for Simultaneous and Ratiometric sequencing operation**

**Table 4 Start-Up Configurations**

| Operating Mode          | $V_{SEQ}$       | Configuration       |
|-------------------------|-----------------|---------------------|
| Internal soft-start     | Floating        | —                   |
| Simultaneous Sequencing | Ramp up from 0V | $R_E/R_F = R_C/R_D$ |
| Ratiometric Sequencing  | Ramp up from 0V | $R_E/R_F > R_C/R_D$ |



**Figure 15 Typical waveforms for sequencing operation: (a) Simultaneous; (b) Ratiometric**

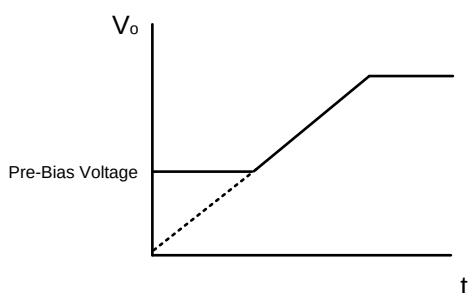
## PRE-BIAS START-UP

IR3827 is able to start up into a pre-charged output smoothly, which prevents oscillations and disturbances of the output voltage.

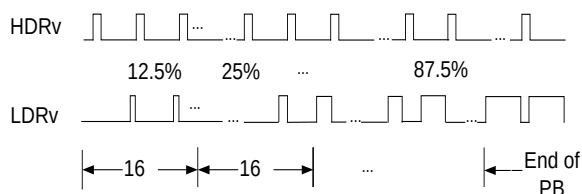


The output starts in an asynchronous fashion and keeps the synchronous MOSFET (Sync FET) off until the first gate signal for control MOSFET (Ctrl FET) is generated. Figure 16 shows a typical Pre-Bias condition at start up. The gate signal of the control FET is determined by the loop compensator. The sync FET always starts with a narrow pulse width (12.5% of a switching period) and gradually increases its duty cycle with a step of 12.5% until it reaches the steady state value. The number of these startup pulses for each step is 16 and it's internally programmed. Figure 17 shows the series of 16x8 startup pulses.

It should be noted that PGood is not active until the first gate signal for control FET is generated. Please refer to Power Good Section for more information.



**Figure 16 Pre-Bias start-up**



**Figure 17 Pre-Bias startup pulses**

## SHUTDOWN

IR3827 can be shut down by pulling the Enable pin below its 1.0V threshold. Both the high side and the low side drivers are pulled low.

## OPERATING FREQUENCY

The switching frequency can be programmed between 300kHz – 1200kHz by connecting an

external resistor from Rt pin to Gnd. Rt can be calculated as follows.

$$F_s = 19954 \times R_t^{-0.953}$$

Where  $F_s$  is in kHz, and  $R_t$  is in k $\Omega$ .

Table 5 shows the different oscillator frequency and its corresponding  $R_t$  for easy reference.

**Table 5 Switching Frequency vs.  $R_t$**

| $R_t$ (k $\Omega$ ) | $F_s$ (kHz) |
|---------------------|-------------|
| 80.6                | 300         |
| 60.4                | 400         |
| 48.7                | 500         |
| 39.2                | 600         |
| 34                  | 700         |
| 29.4                | 800         |
| 26.1                | 900         |
| 23.2                | 1000        |
| 21                  | 1100        |
| 19.1                | 1200        |

## OVER CURRENT PROTECTION

The over current (OC) protection is performed by sensing current through the  $R_{DS(on)}$  of the Synchronous MOSFET. This method enhances the converter's efficiency, reduces cost by eliminating a current sense resistor and any layout related noise issues. The current limit is pre-set internally and is compensated according to the IC temperature. So at different ambient temperature, the over-current trip threshold remains almost constant.

Detailed operation of OCP is explained as follows. Over Current Protection circuit senses the inductor current flowing through the Synchronous MOSFET closer to the valley point. OCP circuit samples this current for 40nsec typically after the rising edge of the PWM set pulse which has a width of 12.5% of the switching period. The PWM pulse starts at the falling edge of the PWM set pulse. This makes valley current sense more robust as current is sensed close to the bottom of the inductor downward slope where transient and switching noise are lower and helps to prevent false tripping due to noise and transient. An OC condition is detected if the load current exceeds the threshold, the converter enters into hiccup mode. PGood will go low and the internal

soft start signal will be pulled low. The converter goes into hiccup mode with some hiccup blanking time as shown in Figure 18. The converter stays in this mode until the over load or short circuit is removed. With different SS\_Select configurations, the hiccup blanking time is different. Please refer to the electrical table for details. The actual DC output current limit point will be greater than the valley point by an amount equal to approximately half of peak to peak inductor ripple current.

$$I_{OCP} = I_{LIMIT} + \frac{\Delta i}{2}$$

$I_{OCP}$  = DC current limit hiccup point

$I_{LIMIT}$  = Over current limit (Valley of Inductor Current)

$\Delta i$  = Peak-to-peak inductor ripple current

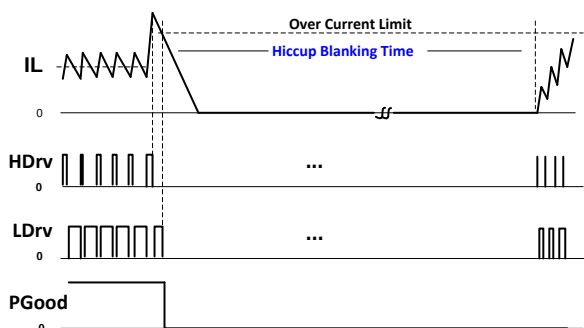


Figure 18 Timing Diagram for Hiccup Over Current Protection

Over current limit is affected by the  $V_{CC}$  voltage. For some single rail operations where  $V_{in}$  is 5V or less, the OCP limit will de-rated due to the drop of  $V_{CC}$  voltage. Figure 19 and Figure 20 show the over current limit for two single rail applications with  $V_{in}=PV_{in}=5V$  and  $V_{in}=PV_{in}=V_{CC}=4.5V$  respectively.

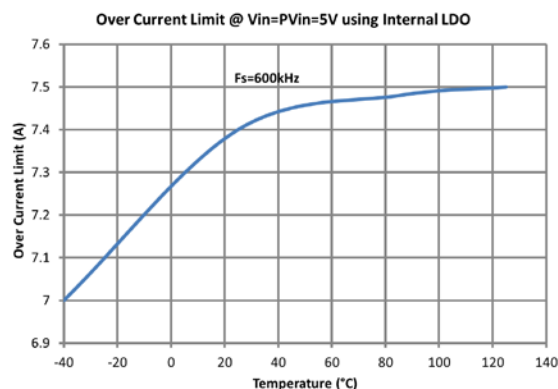


Figure 19 OCP Limit at  $V_{in}=PV_{in}=5V$  using Internal LDO

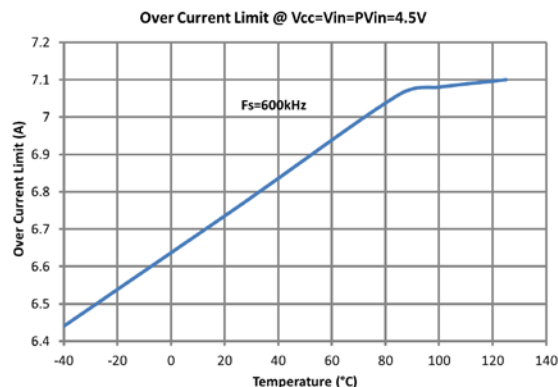


Figure 20 OCP Limit at  $V_{in}=PV_{in}=V_{CC}=4.5V$

## OVER-VOLTAGE PROTECTION (OVP)

Over-voltage protection in IR3827 is achieved by comparing FB pin voltage to a pre-set threshold. OVP threshold is set at  $1.2 \times V_{ref}$ . When FB pin voltage exceeds the over voltage threshold, an over voltage trip signal asserts after 2 $\mu s$  (typ.) delay. Then the high side drive signal HDrv is turned off immediately, PGood flags low. The sync FET remains on to discharge the output capacitor. When the  $V_{FB}$  voltage drops below the threshold, the sync FET turns off to prevent the complete depletion of the output capacitor. After that, HDrv remains off until a reset is performed by cycling either  $V_{CC}$  or Enable. Figure 21 shows the timing diagram for over voltage protection. Please note that OVP comparator becomes active only when the IR3827 is enabled.

## POWER GOOD OUTPUT

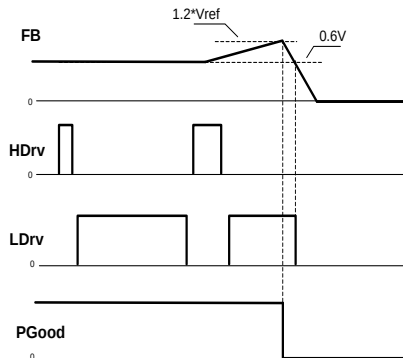
IR3827 continually monitors the output voltage via FB voltage. The FB voltage is an input to the window comparator with upper and lower threshold of 120% and 85% of the reference voltage respectively. PGood signal is high whenever FB voltage is within the PGood comparator window thresholds. For pre-biased start-up, PGood is not active until the first gate signal of the control FET is generated.

The PGood pin is open drain and it needs to be externally pulled high. High state indicates that output is in regulation.

In addition, PGood is also gated by other faults including over current and over temperature. When



either of the faults occurs, PGood pin will be pulled low.



**Figure 21 Timing Diagram for Over Voltage Protection**

## THERMAL SHUTDOWN

Temperature sensing is provided inside IR3827. The trip threshold is typically set to 145°C. When trip threshold is exceeded, thermal shutdown turns off both MOSFETs and resets the internal soft start.

Automatic restart is initiated when the sensed temperature drops within the operating range. There is a 20°C hysteresis in the thermal shutdown threshold.

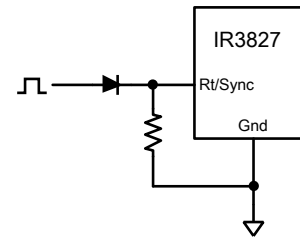
## EXTERNAL SYNCHRONIZATION

IR3827 incorporates an internal phase lock loop (PLL) circuit which enables synchronization of the internal oscillator to an external clock. This function is important to avoid sub-harmonic oscillations due to beat frequency for embedded systems when multiple point-of-load (POL) regulators are used. A multi-function pin, Rt/Sync, is used to connect the external clock. If the external clock is present before the converter turns on, Rt/Sync pin can be connected to the external clock signal solely and no other resistor is needed. If the external clock is applied after the converter turns on, or the converter switching frequency needs to toggle between the external clock frequency and the internal free-running frequency, an external resistor from Rt/Sync pin to Gnd is required to set the free-running frequency.

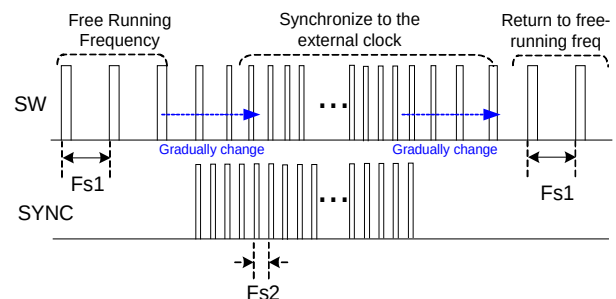
When an external clock is applied to Rt/Sync pin after the converter runs in steady state with its free-

running frequency, a transition from the free-running frequency to the external clock frequency will happen. This transition is to gradually make the actual switching frequency equal to the external clock frequency, no matter which one is higher. On the contrary, when the external clock signal is removed from Rt/Sync pin, the switching frequency is also changed to free-running gradually. In order to minimize the impact from these transitions to output voltage, a diode is recommended to add between the external clock and Rt/Sync pin, as shown in Figure 22. Figure 23 shows the timing diagram of these transitions.

An internal compensation circuit is used to change the PWM ramp slope according to the clock frequency applied on Rt/Sync pin. Thus, the effective amplitude of the PWM ramp ( $V_{ramp}$ ), which is used in compensation loop calculation, has minor impact from the variation of the external synchronization signal.



**Figure 22 Configuration of External Synchronization**



**Figure 23 Timing Diagram for Synchronization to the External Clock ( $Fs1 < Fs2$  or  $Fs1 > Fs2$ )**

## MINIMUM ON TIME CONSIDERATIONS

The minimum ON time is the shortest amount of time for which Ctrl FET may be reliably turned on, and this depends on the internal timing delays. For IR3827, the worst case minimum on-time is specified as 60 ns.

Any design or application using IR3827 must ensure operation with a pulse width that is higher than this minimum on-time and preferably higher than 60ns. This is necessary for the circuit to operate without jitter and pulse-skipping, which can cause high inductor current ripple and high output voltage ripple.

$$t_{on} = \frac{D}{F_s} = \frac{V_{out}}{V_{in} \times F_s}$$

In any application that uses IR3827, the following condition must be satisfied:

$$t_{on(min)} \leq t_{on}$$

$$t_{on(min)} \leq \frac{V_{out}}{V_{in} \times F_s}, \text{ therefore, } V_{in} \times F_s \leq \frac{V_{out}}{t_{on(min)}}$$

The minimum output voltage is limited by the reference voltage and hence  $V_{out(min)} = 0.6 \text{ V}$ . Therefore,

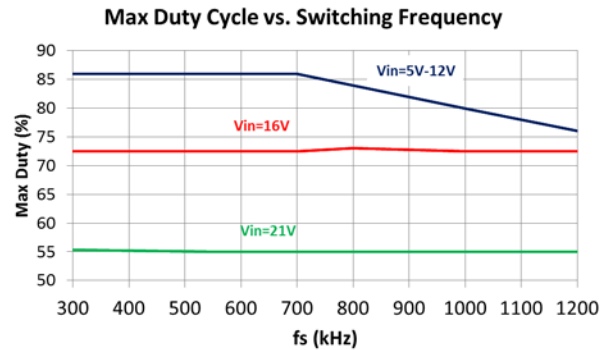
$$V_{in} \times F_s \leq \frac{V_{out(min)}}{t_{on(min)}} = \frac{0.6\text{V}}{60\text{ns}} = 10\text{V} / \mu\text{s}$$

Therefore, at the maximum recommended input voltage 21V and minimum output voltage, the converter should be designed at a switching frequency that does not exceed 476 kHz. Conversely, for operation at the maximum recommended operating frequency (1.32 MHz) and minimum output voltage (0.6V). The input voltage ( $PV_{in}$ ) should not exceed 7.57V, otherwise pulse skipping will happen.

## MAXIMUM DUTY RATIO

A certain off-time is specified for IR3827. This provides an upper limit on the operating duty ratio at any given switching frequency. The off-time remains at a relatively fixed ratio to switching period in low and mid frequency range, while in high frequency

range this ratio increases, thus the lower the maximum duty ratio at which IR3827 can operate. Figure 24 shows a plot of the maximum duty ratio vs. the switching frequency.



**Figure 24** Maximum duty cycle vs. switching frequency.

## DESIGN EXAMPLE

The following example is a typical application for IR3827. The application circuit is shown in Figure 28.

$$PV_{in} = V_{in} = 12V (\pm 10\%)$$

$$V_o = 1.2V$$

$$I_o = 6A$$

$$\text{Peak-to-Peak Ripple Voltage} = \pm 1\% \text{ of } V_o$$

$$\Delta V_o = \pm 4\% \text{ of } V_o \text{ (for 30\% Load Transient)}$$

$$F_s = 600 \text{ kHz}$$

## EXTERNAL PVIN MONITOR (INPUT UVLO)

As explained in the section of Enable/External  $PV_{in}$  monitor, the input voltage,  $PV_{in}$ , can be monitored by connecting the Enable pin to  $PV_{in}$  through a set of resistor divider. When  $PV_{in}$  exceeds the desired voltage level such that the voltage at the Enable pin exceeds the Enable threshold, 1.2V, the IR3827 is turned on. The implementation of this function is shown in Figure 7.

For a typical Enable threshold of  $V_{EN} = 1.2 \text{ V}$

$$PV_{in(min)} \times \frac{R_2}{R_1 + R_2} = V_{EN} = 1.2$$

$$R_2 = R_1 \times \frac{V_{EN}}{PV_{in(min)} - V_{EN}}$$

For the minimum input voltage  $PV_{in(min)} = 9.2V$ , select  $R_1 = 49.9k\Omega$ , and  $R_2 = 7.5k\Omega$ .

## SWITCHING FREQUENCY

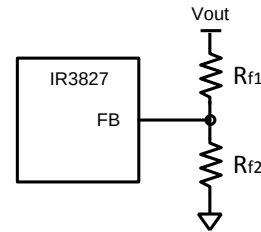
For  $F_s = 600 \text{ kHz}$ , select  $R_t = 39.2 \text{ K}\Omega$ , from Table 5.

## OUTPUT VOLTAGE SETTING

Output voltage is set by the reference voltage and the external voltage divider connected to the FB pin. The FB pin is the inverting input of the error amplifier, which is internally referenced to 0.6V. The divider ratio is set to provide 0.6V at the FB pin when the output is at its desired value. The output voltage is defined by using the following equation:

$$V_o = V_{REF} \times \left(1 + \frac{R_{F1}}{R_{F2}}\right)$$

$R_{F1}$  and  $R_{F2}$  are the feedback resistor divider, as shown in Figure 25. For the selection of  $R_{F1}$  and  $R_{F2}$ , please see feedback compensation section.



**Figure 25** The output voltage is programmed through a set of feedback resistor divider

## BOOTSTRAP CAPACITOR SELECTION

To drive the Control FET, it is necessary to supply a gate voltage at least 4V greater than the voltage at the SW pin, which is connected to the source of the Control FET. This is achieved by using a bootstrap configuration, which comprises the internal bootstrap diode and an external bootstrap capacitor, C1, as shown in Figure 26. The operation of the circuit is as follows: When the sync FET is turned on, the capacitor node connected to SW is pulled low.  $V_{CC}$  starts to charge C1 through the internal bootstrap diode. The voltage,  $V_C$ , across the bootstrap capacitor C1 can be calculated as

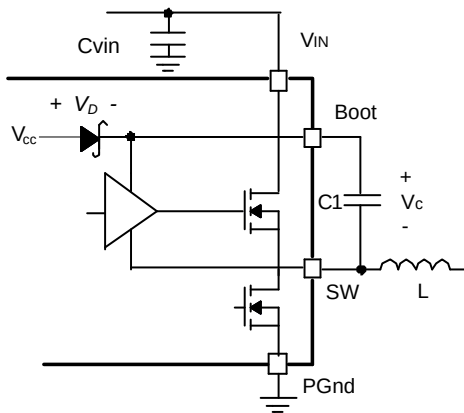
$$V_C = V_{CC} - V_D$$

where  $V_D$  is the forward voltage drop of the bootstrap diode.

When the control FET turns on in the next cycle, the SW node voltage rises to the bus voltage,  $PV_{in}$ . The voltage at the Boot pin becomes:

$$V_{BOOT} = PV_{in} + V_{CC} - V_D$$

A good quality ceramic capacitor of  $0.1\mu F$  with voltage rating of at least 25V is recommended for most applications.



**Figure 26 Bootstrap circuit to generate the supply voltage for the high-side driver voltage**

### INPUT CAPACITOR SELECTION

Good quality input capacitors are necessary to minimize the input ripple voltage and to supply the switch current during the on-time. The input capacitors should be selected based on the RMS value of the input ripple current and requirement of the input ripple voltage.

The RMS value of the input ripple current can be calculated as follows:

$$I_{RMS} = I_o \times \sqrt{D \times (1-D)}$$

Where D is the duty cycle and  $I_o$  is the output current. For  $I_o=6A$  and  $D=0.1$ ,  $I_{RMS}= 1.8A$

The input voltage ripple is the result of the charging of the input capacitors and the voltage induced by ESR and ESL of the input capacitors.

Ceramic capacitors are recommended due to their high ripple current capabilities. They also feature low ESR and ESL at higher frequency which enables better efficiency.

For this application, it is suggested to use three 10μF/25V ceramic capacitors, C3216X5R1E106M, from TDK. In addition, although not mandatory, a 1x330uF, 25V SMD capacitor EEV-FK1E331P from Panasonic may also be used as a bulk capacitor and is recommended if the input power supply is not located close to the converter.

### INDUCTOR SELECTION

The inductor is selected based on output power, operating frequency and efficiency requirements. A low inductor value causes large ripple current, resulting in the smaller size, faster response to a load transient but poor efficiency and high output noise. Generally, the selection of the inductor value can be reduced to the desired maximum ripple current in the inductor ( $\Delta i$ ). The optimum point is usually found between 20% and 50% ripple of the output current.

The saturation current of the inductor is desired to be higher than the over current limit plus the inductor ripple current. An inductor with soft-saturation characteristic is recommended.

For the buck converter, the inductor value for the desired operating ripple current can be determined using the following relation:

$$PV_{inmax} - V_o = L \times \frac{\Delta i_{Lmax}}{\Delta t}; \Delta t = \frac{D}{F_s}$$

$$L = (PV_{inmax} - V_o) \times \frac{V_o}{V_{in} \times \Delta i_{Lmax} \times F_s}$$

Where:

$PV_{inmax}$  = Maximum input voltage

$V_o$  = Output Voltage

$\Delta i_{Lmax}$  = Maximum Inductor Peak-to-Peak Ripple Current

$F_s$  = Switching Frequency

$\Delta t$  = On time

D = Duty Cycle

Select  $\Delta i_{Lmax} \approx 30\% \times I_o$ , then the output inductor is calculated to be 1.0μH. Select L=1.0μH, SPM6550T-1R0M, from TDK which provides a compact, low profile inductor suitable for this application.

### OUTPUT CAPACITOR SELECTION

Output capacitors are usually selected to meet two specific requirements: (1) Output ripple voltage and (2) load transient response. The load transient response is also greatly affected by the control bandwidth. So it is common practice to select the output capacitors to meet the requirements of the

output ripple voltage first, and then design the control bandwidth to meet the transient load response. For some cases, even with the highest allowable control bandwidth, the resulting load transient response still cannot meet the requirement. The number of output capacitors then need to be increased.

The voltage ripple is attributed by the ripple current charging the output capacitors, and the voltage drop due to the Equivalent Series Resistance (ESR) and the Equivalent Series Inductance (ESL). Following lists the respective peak-to-peak ripple voltages:

$$\Delta V_{o(C)} = \frac{\Delta i_{Lmax}}{8 \times C_o \times F_s}$$

$$\Delta V_{o(ESR)} = \Delta i_{Lmax} \times ESR$$

$$\Delta V_{o(ESL)} = \left( \frac{P V_{in} - V_o}{L} \right) \times ESL$$

Where  $\Delta i_{Lmax}$  is maximum inductor peak-to-peak ripple current.

Good quality ceramic capacitors are recommended due to their low ESR, ESL and the small package size. It should be noted that the capacitance of ceramic capacitors are usually de-rated with the DC and AC biased voltage. It is important to use the de-rated capacitance value for the calculation of output ripple voltage as well as the voltage loop compensation design. The de-rated capacitance value may be obtained from the manufacturer's datasheets.

In this case, three 22uF ceramic capacitors, C2012X5R0J226M, from TDK are used to achieve  $\pm 12\text{mV}$  peak-to-peak ripple voltage requirement. The de-rated capacitance value with 1.2VDC bias and 10mVAC voltage is around 18uF each.

## FEEDBACK COMPENSATION

For this design, the resonant frequency of the output LC filter,  $F_{LC}$ , is

$$F_{LC} = \frac{1}{2 \times \pi \sqrt{L_o \times C_o}}$$

$$= \frac{1}{2 \times \pi \sqrt{1.0 \times 10^{-6} \times 3 \times 18 \times 10^{-6}}}$$

$$= 21.6\text{kHz}$$

The equivalent ESR zero of the output capacitors,  $F_{ESR}$ , is.

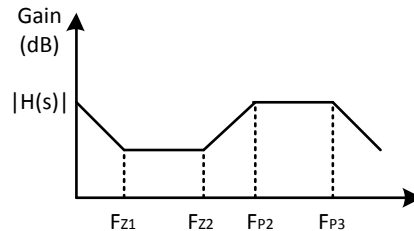
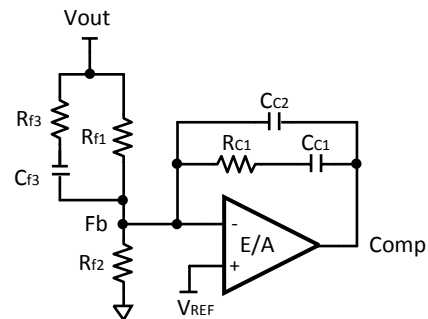
$$F_{ESR} = \frac{1}{2\pi \times \frac{ESR}{3} \times 3 \times C_o}$$

$$= \frac{1}{2\pi \times 3 \times 10^{-3} \times 18 \times 10^{-6}}$$

$$= 2.95 \times 10^3 \text{kHz}$$

Select crossover frequency  $F_0=100\text{kHz}$

According to Table 1, Type III B compensation is selected for  $F_{LC} < F_0 < F_s/2 < F_{ESR}$ . Type III compensator is shown below for easy reference.



**Figure 27 Type III compensation and its asymptotic gain plot**

$$F_{Z1} = \frac{1}{2\pi \times R_{C1} \times C_{C1}}$$

$$F_{Z2} = \frac{1}{2\pi \times C_{F3} \times (R_{F3} + R_{F1})}$$

$$F_{P1} = 0$$

$$F_{P2} = \frac{1}{2\pi \times R_{F3} \times C_{F3}}$$

$$F_{P3} = \frac{1}{2\pi \times R_{C1} \times C_{C2}}$$

$F_{Z2}$  and  $F_{P2}$  are selected to achieve phase boost  $\Theta=70^\circ$ .

$$F_{Z2} = F_0 \sqrt{\frac{1-\sin \theta}{1+\sin \theta}} = 100 \times 10^3 \sqrt{\frac{1-\sin 70}{1+\sin 70}} = 17.6\text{kHz}$$

$$F_{P2} = F_0 \sqrt{\frac{1+\sin \theta}{1-\sin \theta}} = 100 \times 10^3 \sqrt{\frac{1+\sin 70}{1-\sin 70}} = 568\text{kHz}$$

$F_{Z1}$  is selected to provide extra phase boost.

$$F_{Z1} = F_{Z2} / 2 = 8.8\text{kHz}$$

$F_{P3}$  is set at one half of the switching frequency to damp the switching noise.

$$F_{P3} = F_s / 2 = 300\text{kHz}$$

The selected compensation parameters are:  
 $R_{F1}=3.32\text{k}\Omega$ ,  $R_{F2}=3.32\text{k}\Omega$ ,  $R_{F3}=100\Omega$ ,  $C_{F3}=2200\text{pF}$ ,  
 $R_{C1}=2\text{k}\Omega$ ,  $C_{C1}=10\text{nF}$ ,  $C_{C2}=180\text{pF}$ .

## APPLICATION DIAGRAM

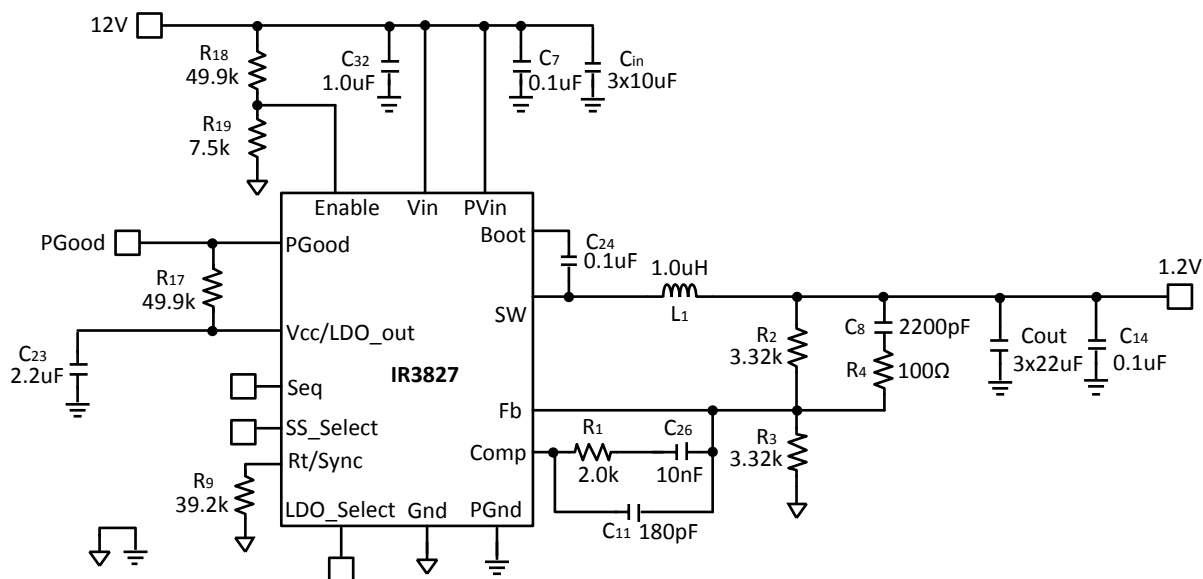
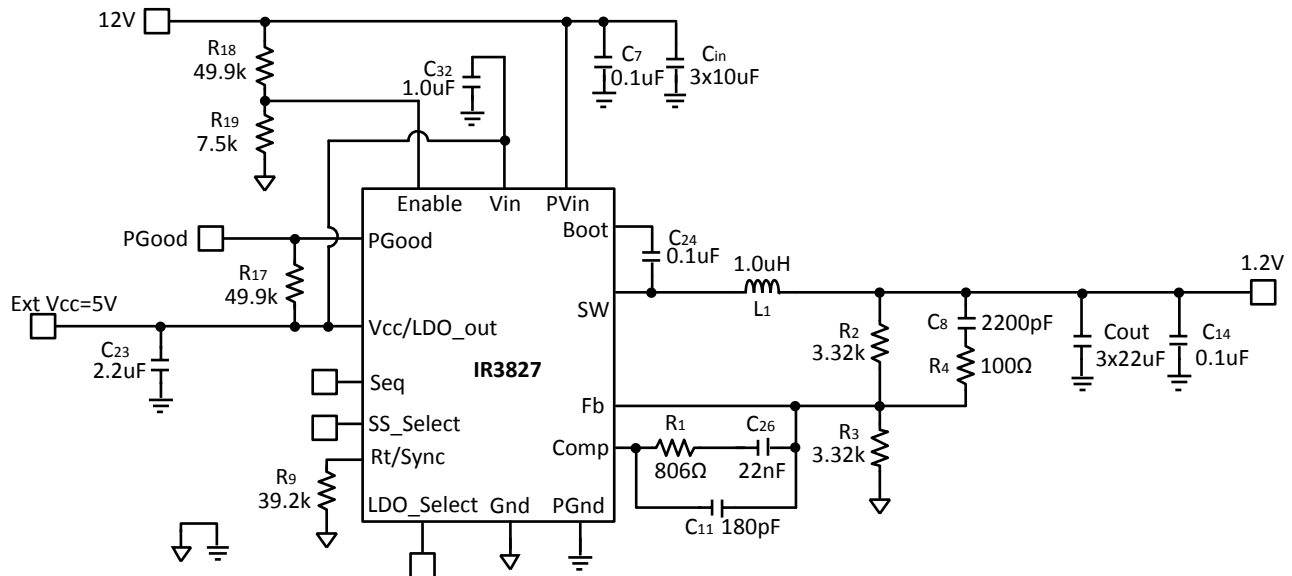


Figure 28 Single Rail 6A POL Application Circuit:  $PV_{in}=V_{in}=12V$ ,  $V_o=1.2V$ ,  $I_o=6A$ ,  $f_{sw}=600kHz$

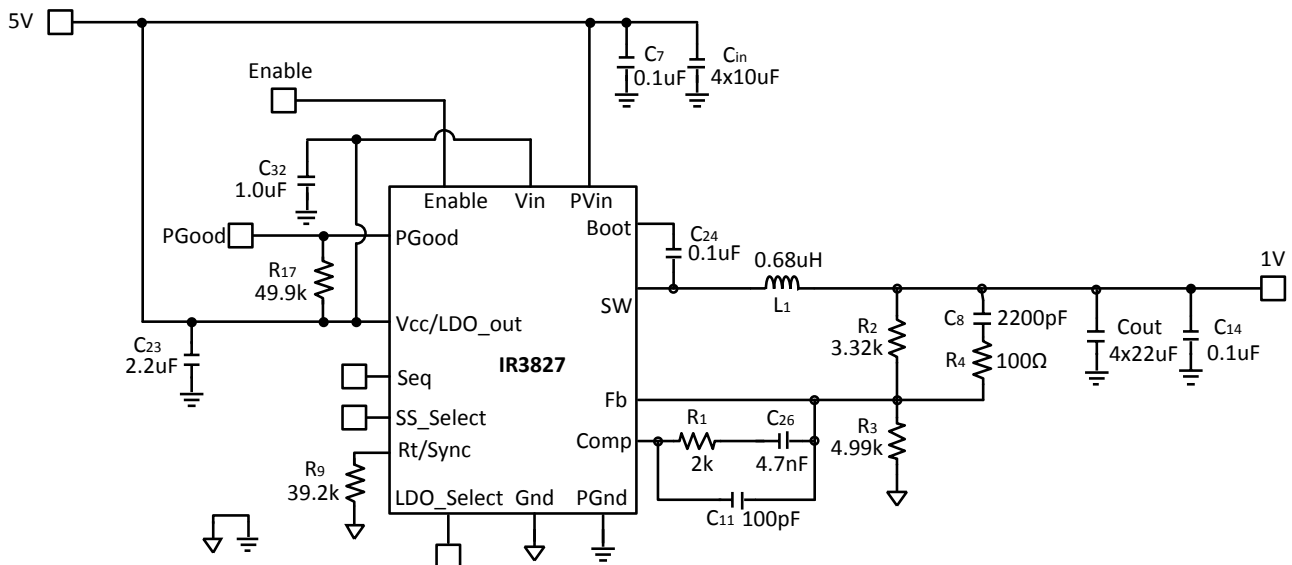
## SUGGESTED BILL OF MATERIALS

| QTY | PART REFERENCE   | VALUE  | DESCRIPTION                 | MANUFACTURER | PART NUMBER        |
|-----|------------------|--------|-----------------------------|--------------|--------------------|
| 3   | C <sub>in</sub>  | 10uF   | 1206, 25V, X5R, 20%         | TDK          | C3216X5R1E106M     |
| 3   | C7 C14 C24       | 0.1uF  | 0603, 25V, X7R, 10%         | Murata       | GRM188R71E104KA01B |
| 1   | C8               | 2200pF | 0603, 50V, X7R              | Murata       | GRM188R71H222KA01B |
| 1   | C11              | 180pF  | 0603, 50V, NP0, 5%          | Murata       | GRM1885C1H181JA01D |
| 3   | C <sub>out</sub> | 22uF   | 0805, 6.3V, X5R, 20%        | TDK          | C2012X5R0J226M     |
| 1   | C23              | 2.2uF  | 0603, 16V, X5R, 20%         | TDK          | C1608X5R1C225M     |
| 1   | C26              | 10nF   | 0603, 25V, X7R, 10%         | Murata       | GRM188R71E103KA01J |
| 1   | C32              | 1.0uF  | 0603, 25V, X5R, 10%         | Murata       | GRM188R61E105KA12D |
| 1   | L1               | 1.0uH  | SMD 7.1x6.5x5mm, 4.7mΩ      | TDK          | SPM6550T-1R0       |
| 1   | R1               | 2K     | Thick Film, 0603, 1/10W, 1% | Panasonic    | ERJ-3EKF2001V      |
| 2   | R2, R3           | 3.32K  | Thick Film, 0603, 1/10W, 1% | Panasonic    | ERJ-3EKF3321V      |
| 1   | R4               | 100    | Thick Film, 0603, 1/10W, 1% | Panasonic    | ERJ-3EKF1000V      |
| 1   | R9               | 39.2K  | Thick Film, 0603, 1/10W, 1% | Panasonic    | ERJ-3EKF3922V      |
| 2   | R17 R18          | 49.9K  | Thick Film, 0603, 1/10W, 1% | Panasonic    | ERJ-3EKF4992V      |
| 1   | R19              | 7.5K   | Thick Film, 0603, 1/10W, 1% | Panasonic    | ERJ-3EKF7501V      |
| 1   | U1               | IR3827 | PQFN 4x5mm                  | IR           | IR3827MPBF         |

# APPLICATION DIAGRAM



**Figure 29 6A POL Application Circuit with external 5V  $V_{CC}$ :  $PV_{in}=V_{in}=12V$ ,  $V_o=1.2V$ ,  $I_o=6A$ ,  $f_{sw}=600kHz$ . Please note that loop compensation is adjusted to consider the absence of the input voltage feedforward.**

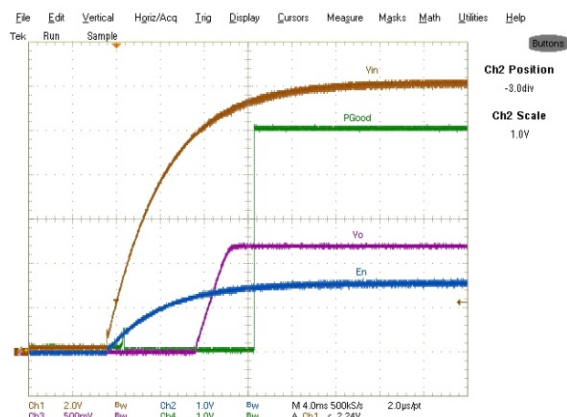


**Figure 30 Single Rail 6A POL Application Circuit:  $PV_{in}=V_{in}=5V$ ,  $V_o=1.0V$ ,  $I_o=6A$ ,  $f_{sw}=600kHz$**

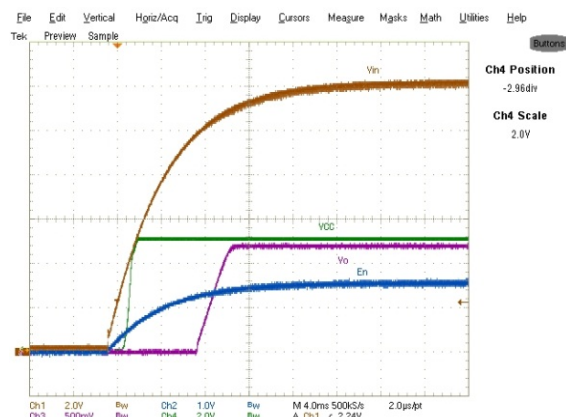


## TYPICAL OPERATING WAVEFORMS

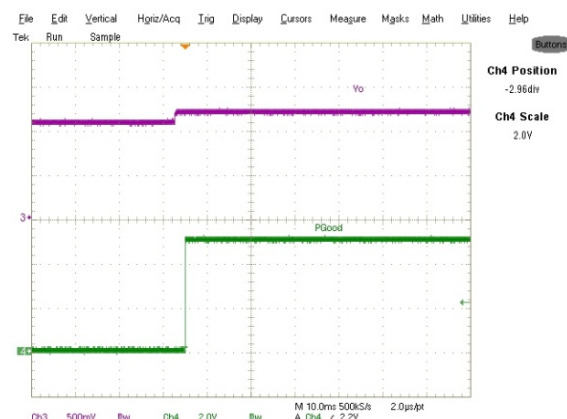
$V_{in} = 12V$ ,  $V_o = 1.2V$ ,  $I_o = 0-6A$ , Unless otherwise Specified, LDO\_Select = Float. Room Temperature, No Air Flow



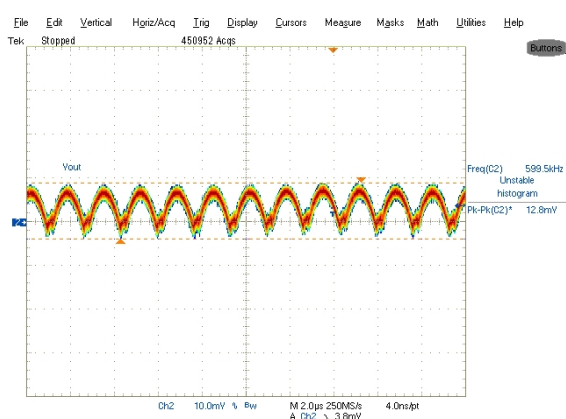
**Figure 31 Start up at 6A Load with SS\_Select pin floating. Ch1:V<sub>in</sub>, Ch2:Enable, Ch3:V<sub>o</sub>, Ch4: P<sub>Good</sub>**



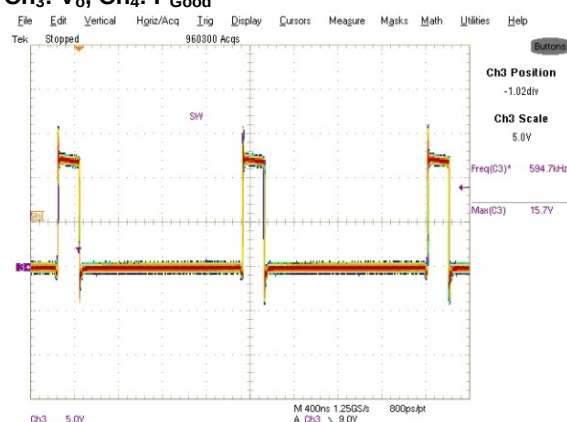
**Figure 32 Start up at 6A Load with SS\_Select pin floating. Ch1:V<sub>in</sub>, Ch2:Enable, Ch3:V<sub>o</sub>, Ch4:V<sub>CC</sub>**



**Figure 33 Start up with 1.06V Pre Bias, 0A Load Ch3: V<sub>o</sub>, Ch4: P<sub>Good</sub>**



**Figure 34 Output Voltage Ripple, 6A load Ch2: V<sub>out</sub>**



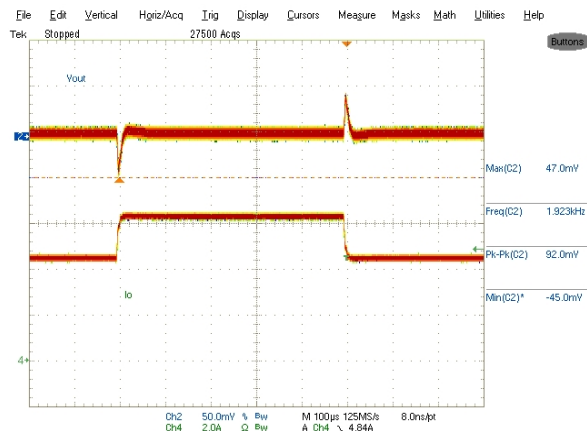
**Figure 35 Inductor node at 6A load, LDO\_Select = Float Ch3:LX**



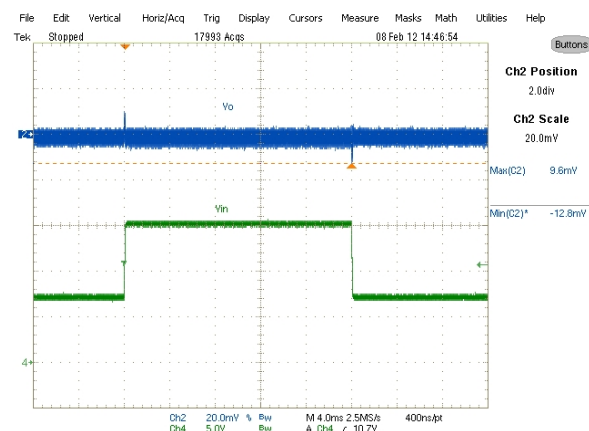
**Figure 36 Short circuit (Hiccup) Recovery, SS\_Select = Float, Ch3:V<sub>out</sub>, Ch4:I<sub>out</sub>**

## TYPICAL OPERATING WAVEFORMS

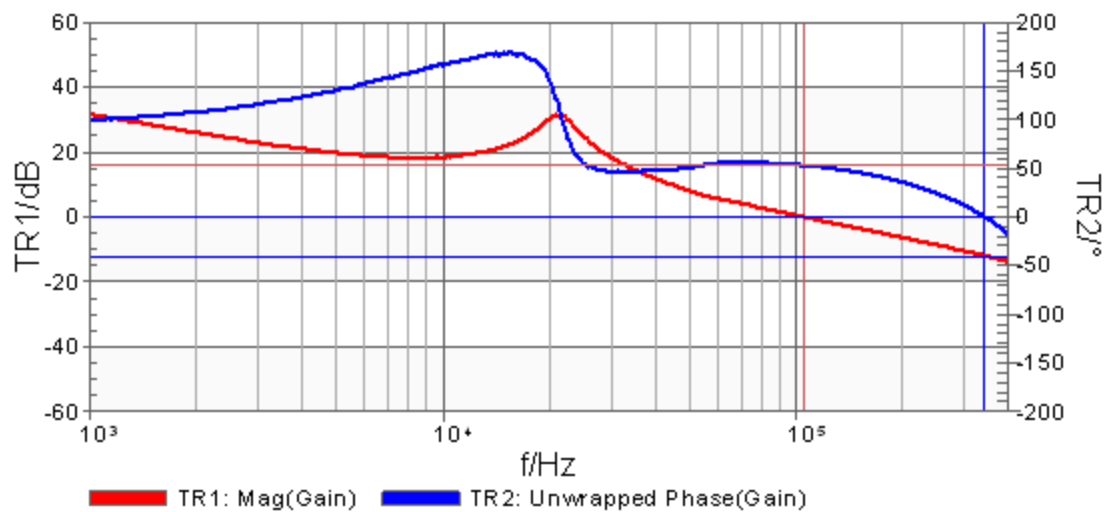
$V_{in} = 12V$ ,  $V_o = 1.2V$ ,  $I_o = 0-6A$ , Unless otherwise Specified, LDO\_Select = Float. Room Temperature, No Air Flow



**Figure 37 Transient Response, 4.2A to 6A**  
Step load Ch2:V<sub>out</sub> Ch4:I<sub>out</sub>



**Figure 38 Feed Forward for  $V_{in}$  change**  
from 6.8 to 15V and back to 6.8V. Ch2-V<sub>out</sub>, Ch4-V<sub>in</sub>



|             | Frequency   | Trace1     | Trace2    |
|-------------|-------------|------------|-----------|
| Cursor 1    | 105.329 kHz | 0.000 dB   | 53.244 °  |
| Cursor 2    | 343.000 kHz | -11.966 dB | 0.000 °   |
| Delta C2-C1 | 237.671 kHz | -11.966 dB | -53.244 ° |

**Figure 39 Bode Plot at 6A load, bandwidth = 105 kHz, and phase margin = 53 degrees and gain margin = -12dB**

## TYPICAL OPERATING WAVEFORMS

$V_{in} = 12V$ ,  $V_o = 1.2V$ ,  $I_o = 0-6A$ , Unless otherwise Specified, LDO\_Select = Float. Room Temperature, No Air Flow

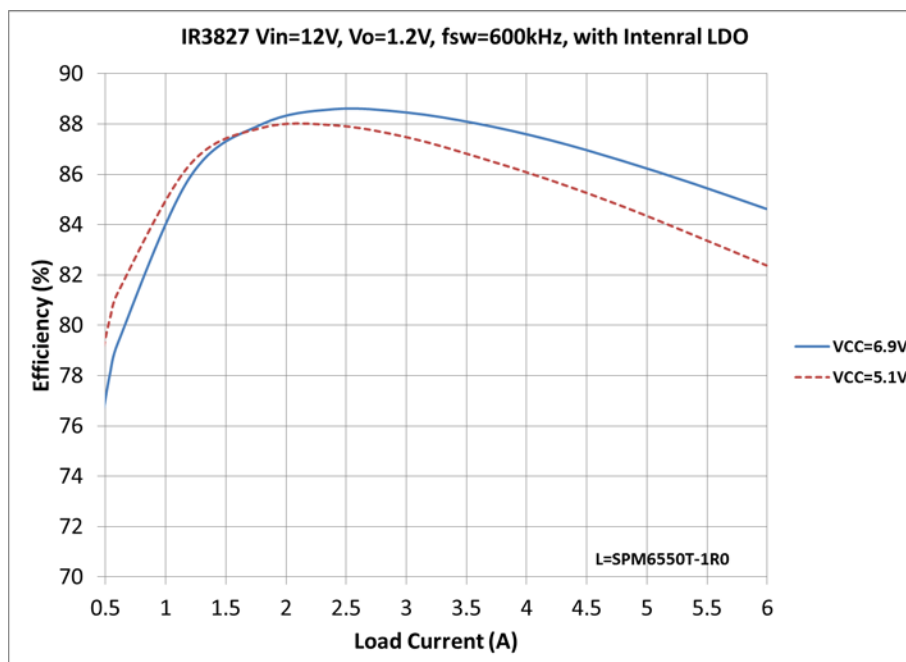


Figure 40 Efficiency vs. Load Current, LDO\_Select = Gnd and Float

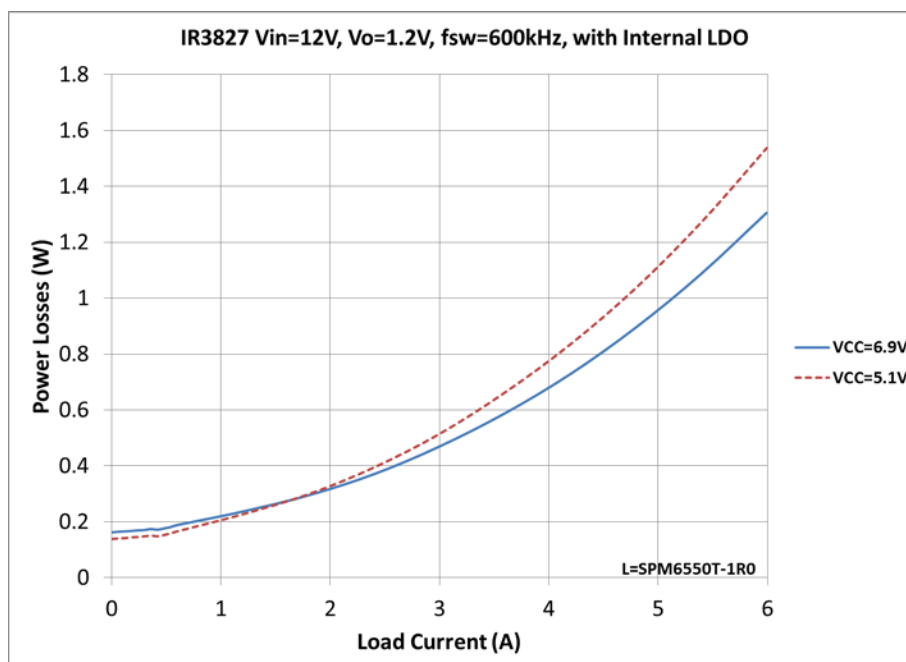


Figure 41 Power Loss vs. Load Current, LDO\_Select = Gnd and Float

## TYPICAL OPERATING WAVEFORMS

$V_{in} = 12V$ ,  $V_o = 1.2V$ ,  $I_o = 0-6A$ , Unless otherwise Specified, LDO\_Select = Float. Room Temperature, No Air Flow

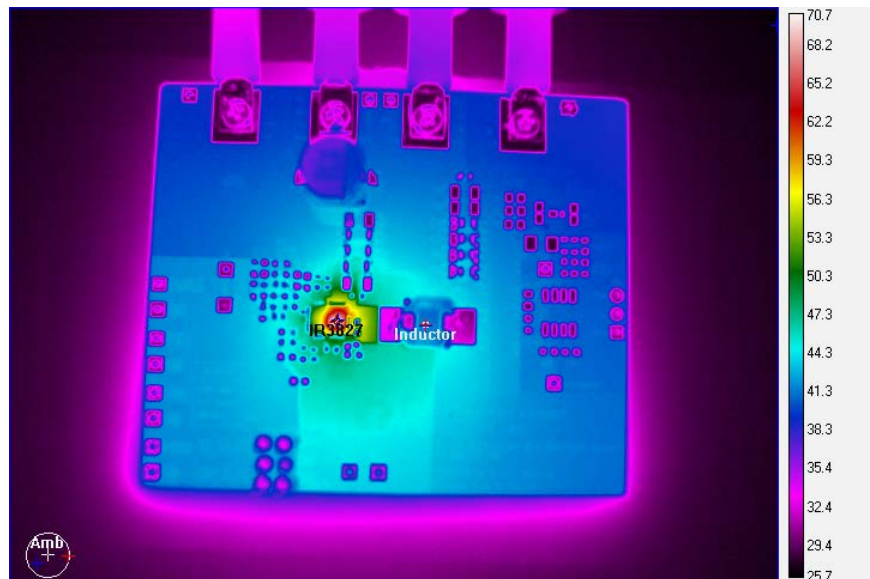


Figure 42 Thermal Image of the board at 6A load, LDO\_Select= Float (VCC=5.1V)  
IR3827=70°C, Inductor=40°C

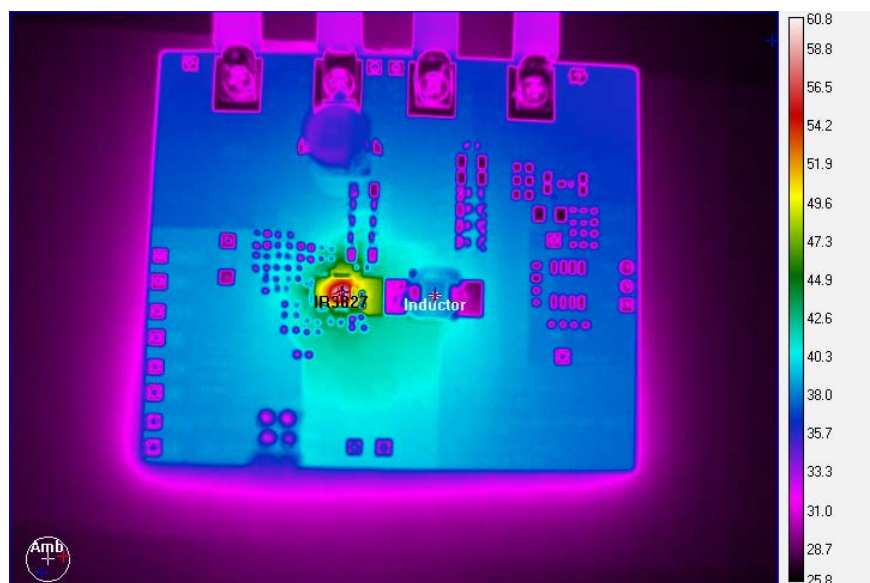


Figure 43 Thermal Image of the board at 6A load, LDO\_Select= GND (VCC=6.9V)  
IR3827=60°C, Inductor=38°C

## LAYOUT RECOMMENDATIONS

The layout is very important when designing high frequency switching converters. Layout will affect noise pickup and can cause a good design to perform with worse than expected results.

Make the connections for the power components in the top layer with wide, copper filled areas or polygons. In general, it is desirable to make proper use of power planes and polygons for power distribution and heat dissipation.

The inductor, output capacitors and the IR3827 should be as close to each other as possible. This helps to reduce the EMI radiated by the power traces due to the high switching currents through them. Place the input capacitor directly at the  $PV_{in}$  pin of IR3827.

The feedback part of the system should be kept away from the inductor and other noise sources.

The critical bypass components such as capacitors for  $V_{in}$  and  $V_{CC}$  should be close to their respective

pins. It is important to place the feedback components including feedback resistors and compensation components close to Fb and Comp pins.

In a multilayer PCB use one layer as a power ground plane and have a control circuit ground (analog ground), to which all signals are referenced. The goal is to localize the high current path to a separate loop that does not interfere with the more sensitive analog control function. These two grounds must be connected together on the PC board layout at a single point. It is recommended to place all the compensation parts over the analog ground plane in top layer.

The Power QFN is a thermally enhanced package. Based on thermal performance it is recommended to use at least a 4-layers PCB. To effectively remove heat from the device the exposed pad should be connected to the ground plane using via holes. Figure 44-Figure 47 illustrates the implementation of the layout guidelines outlined above, on the IRDC3827 4-layer demo board.

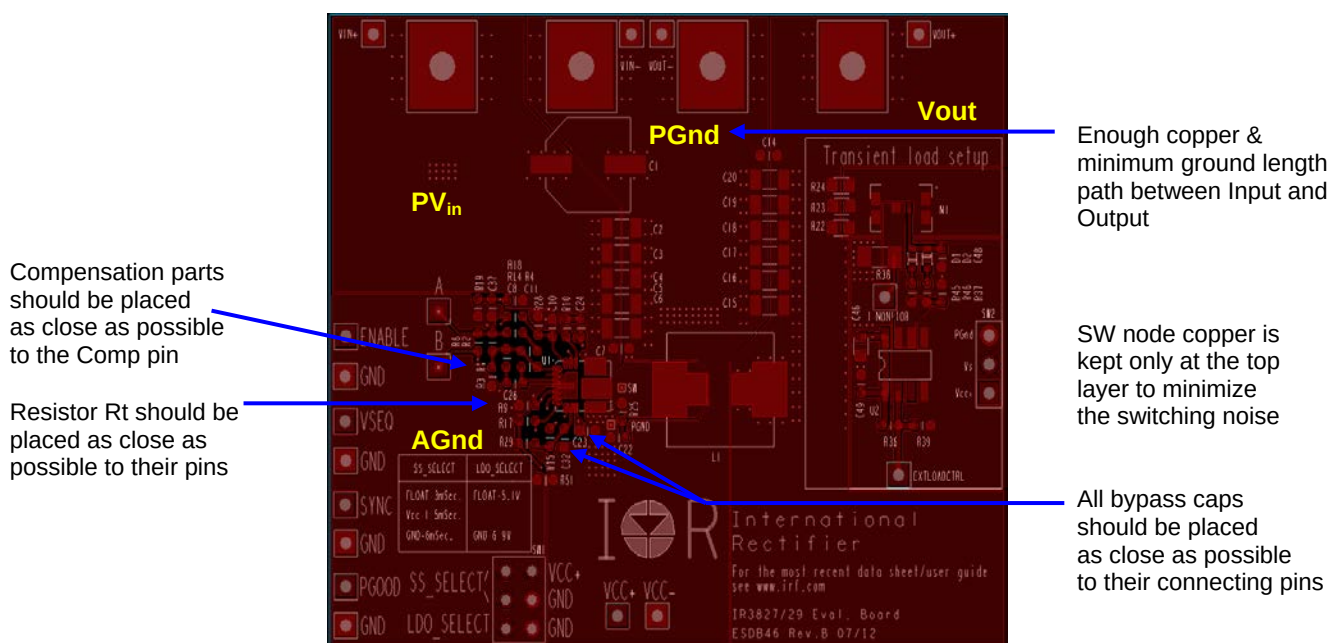


Figure 44 IRDC3827 Demo Board – Top Layer

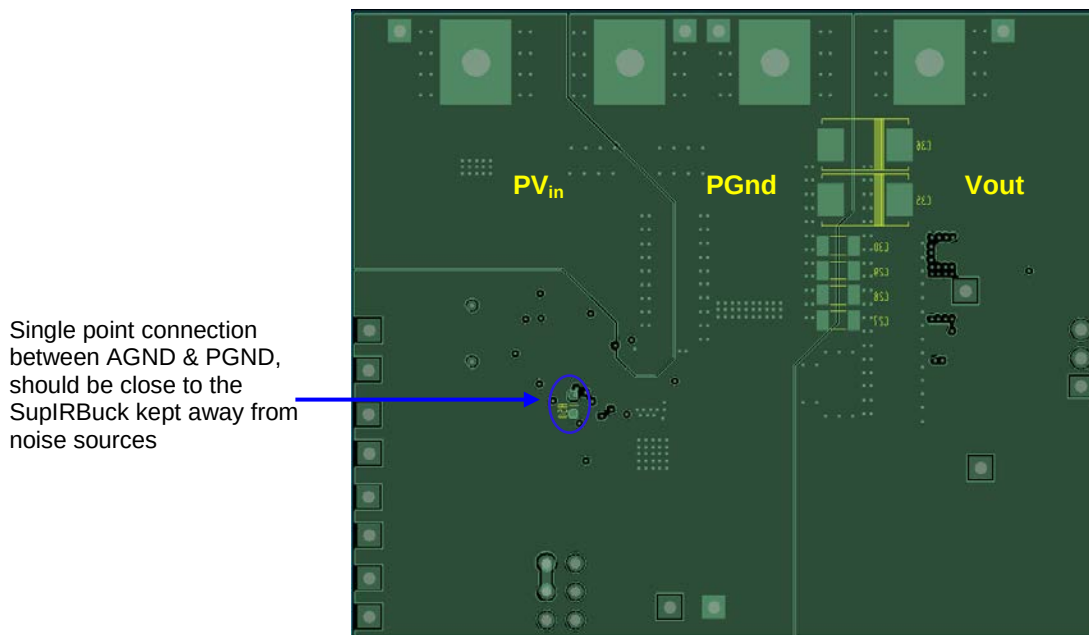


Figure 45 IRDC3827 Demo Board – Bottom Layer

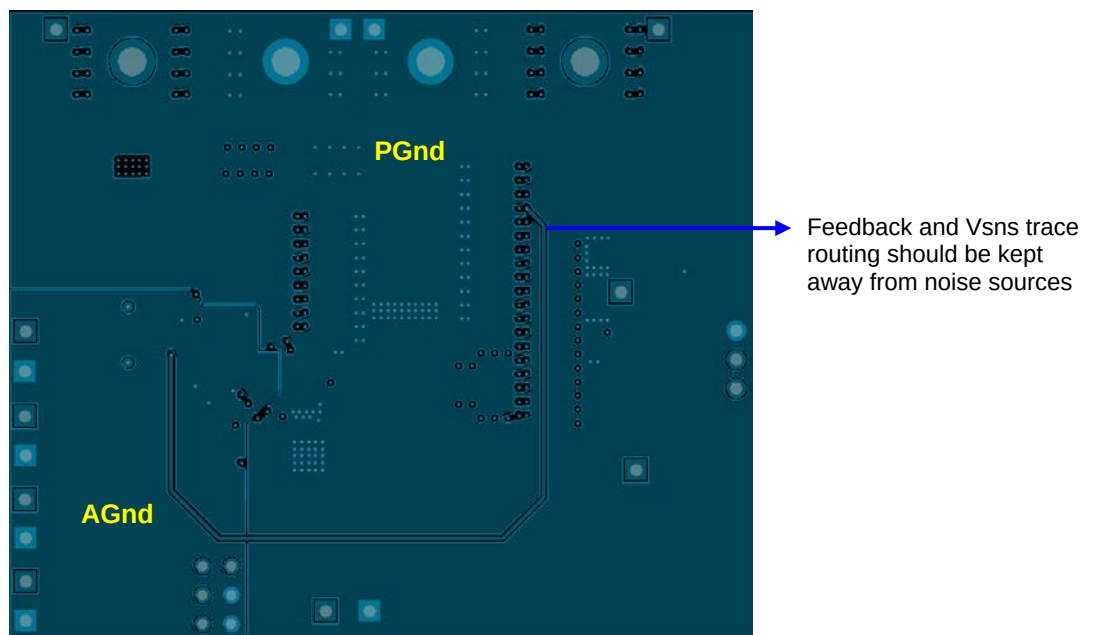


Figure 46 IRDC3827 Demo Board – Middle Layer 1



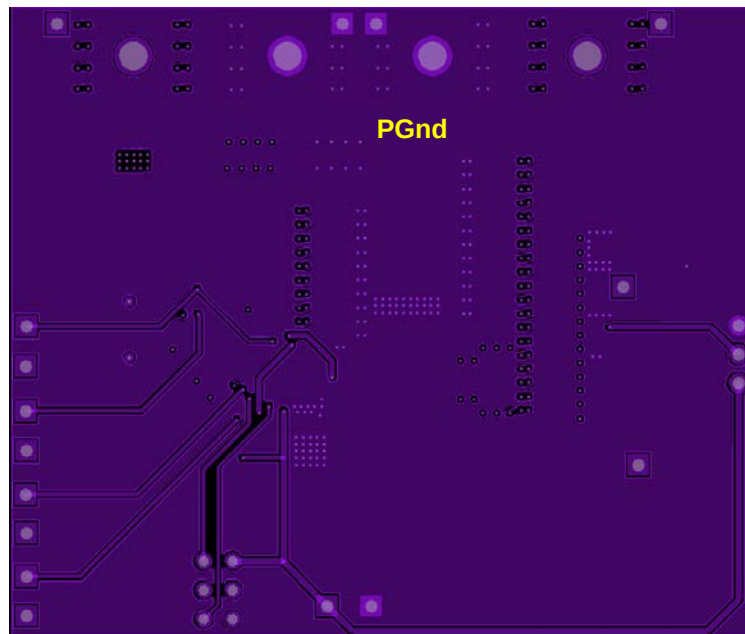


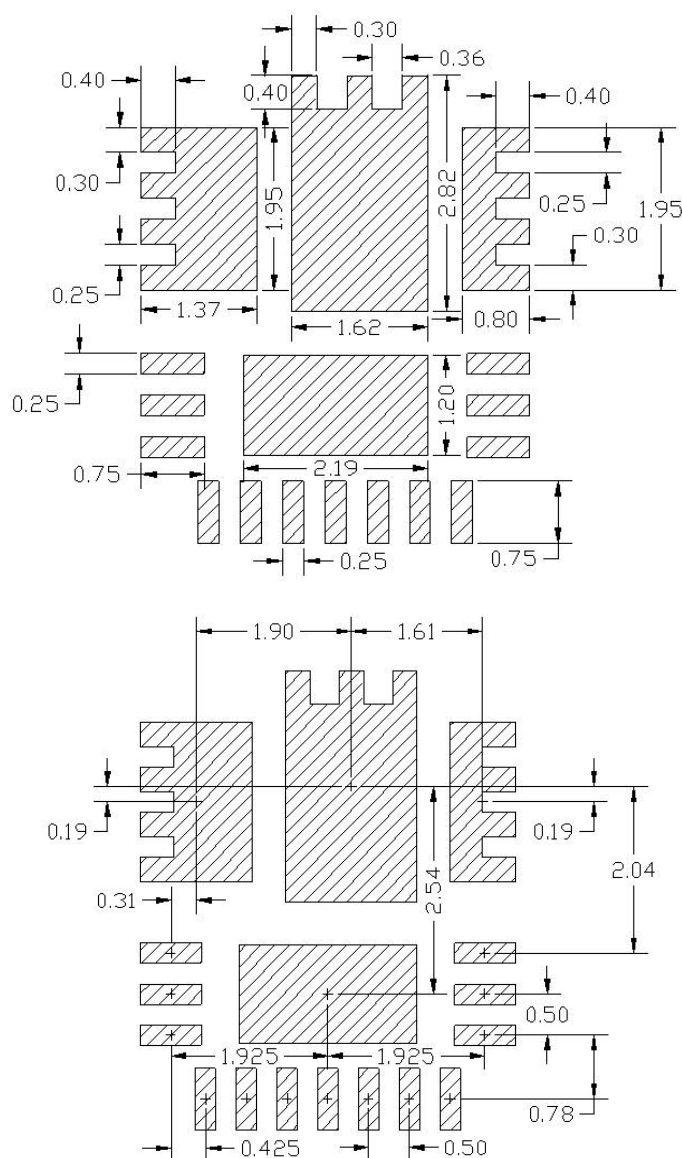
Figure 47 IRDC3827 Demo Board – Middle Layer 2

## PCB METAL AND COMPONENT PLACEMENT

Evaluations have shown that the best overall performance is achieved using the substrate/PCB layout as shown in following figures. PQFN devices should be placed to an accuracy of 0.050mm on both X and Y axes. Self-centering behavior is highly

dependent on solders and processes, and experiments should be run to confirm the limits of self-centering on specific processes.

For further information, please refer to “SupIRBuck™ Multi-Chip Module (MCM) Power Quad Flat No-Lead (PQFN) Board Mounting Application Note.” (AN1132)



**Figure 48 PCB Metal Pad Spacing (all dimensions in mm)**

\* Contact International Rectifier to receive an electronic PCB Library file in your preferred format



## SOLDER RESIST

IR recommends that the larger Power or Land Area pads are Solder Mask Defined (SMD.) This allows the underlying Copper traces to be as large as possible, which helps in terms of current carrying capability and device cooling capability.

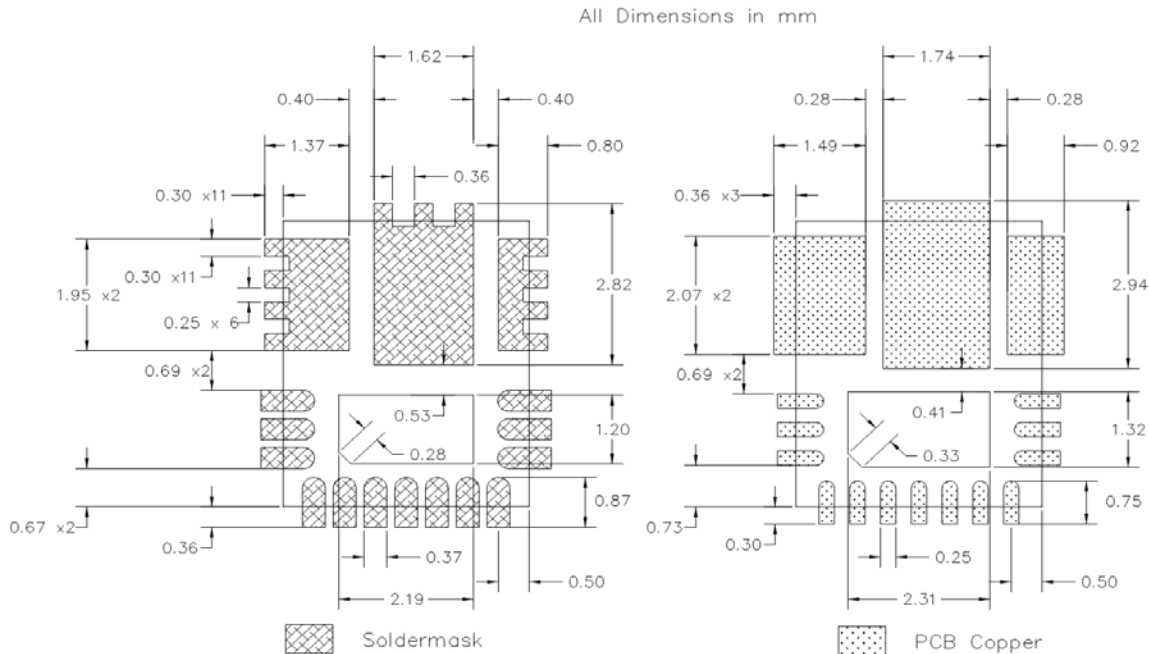
When using SMD pads, the underlying copper traces should be at least 0.05mm larger (on each edge) than the Solder Mask window, in order to accommodate any layer to layer misalignment. (i.e. 0.1mm in X & Y.)

However, for the smaller Signal type leads around the edge of the device, IR recommends that these

are Non Solder Mask Defined (NSMD) or Copper Defined.

When using NSMD pads, the Solder Resist Window should be larger than the Copper Pad by at least 0.025mm on each edge, (i.e. 0.05mm in X&Y,) in order to accommodate any layer to layer misalignment.

Ensure that the solder resist in-between the smaller signal lead areas are at least 0.15mm wide, due to the high x/y aspect ratio of the solder mask strip.

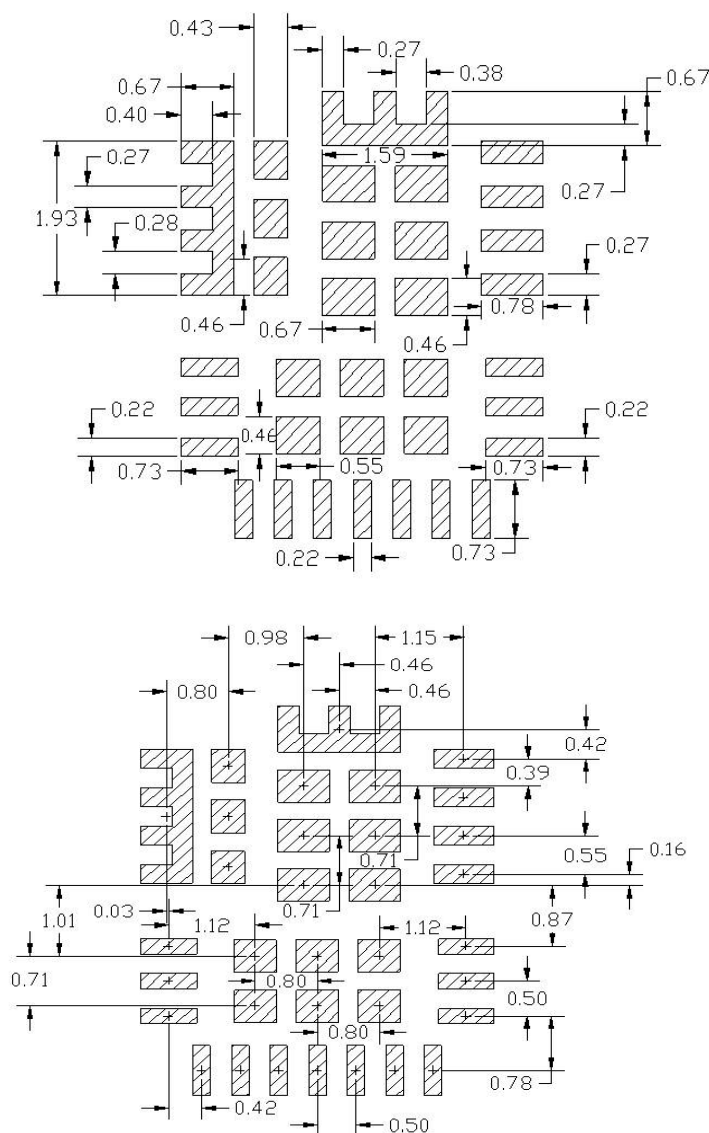


**Figure 49 Solder Resist**

## STENCIL DESIGN

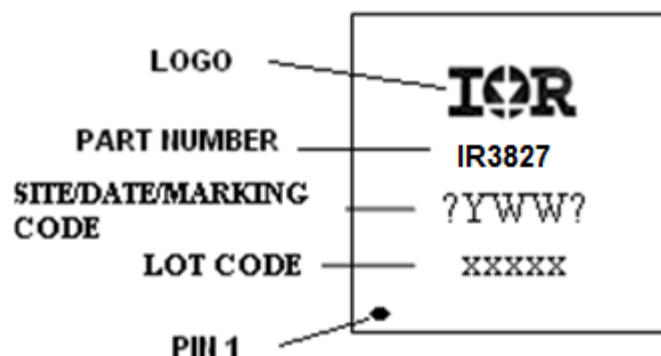
Stencils for PQFN can be used with thicknesses of 0.100-0.250mm (0.004-0.010"). Stencils thinner than 0.100mm are unsuitable because they deposit insufficient solder paste to make good solder joints with the ground pad; high reductions sometimes create similar problems. Stencils in the range of 0.125mm-0.200mm (0.005-0.008"), with suitable reductions, give the best results.

Evaluations have shown that the best overall performance is achieved using the stencil design shown in following figure. This design is for a stencil thickness of 0.127mm (0.005"). The reduction should be adjusted for stencils of other thicknesses.

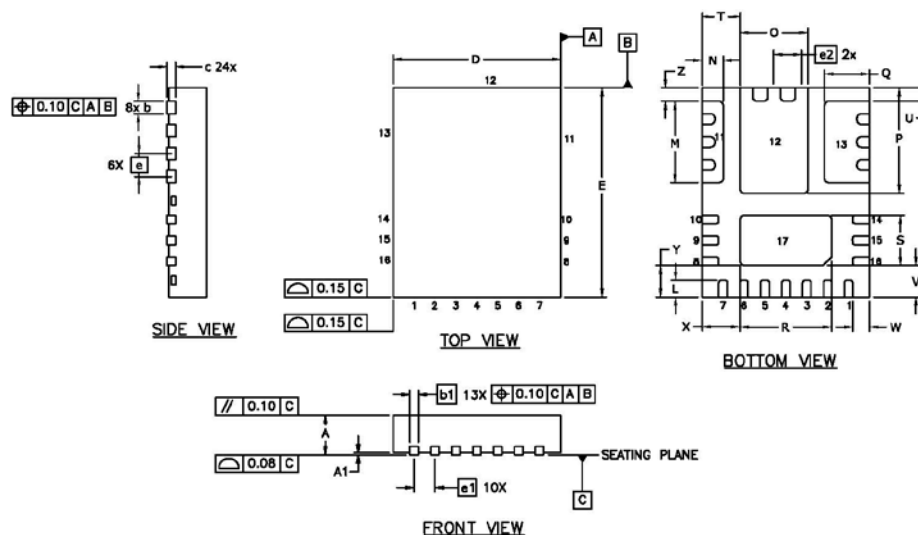


**Figure 50 Stencil Pad Spacing (all dimensions in mm)**

## MARKING INFORMATION



## PACKAGE INFORMATION



| DIM | MILLIMETERS |       | INCHES |       |
|-----|-------------|-------|--------|-------|
|     | MIN         | MAX   | MIN    | MAX   |
| A   | 0.800       | 1.000 | .0315  | .0394 |
| A1  | 0.000       | 0.050 | .0000  | .0020 |
| b   | 0.250       | 0.350 | .0098  | .0138 |
| b1  | 0.150       | 0.250 | .0059  | .0098 |
| c   | 0.203       | REF.  | .0080  | REF.  |
| D   | 4.000       | BASIC | .1575  | BASIC |
| E   | 5.000       | BASIC | .1969  | BASIC |
| e   | 0.550       | BASIC | .0217  | BASIC |
| e1  | 0.500       | BASIC | .0197  | BASIC |
| e2  | 0.659       | BASIC | .0259  | BASIC |
| L   | 0.350       | 0.450 | .0138  | .0177 |
| M   | 1.900       | 2.000 | .0748  | .0787 |
| N   | 0.453       | 0.553 | .0178  | .0218 |
| O   | 1.567       | 1.667 | .0617  | .0656 |
| P   | 2.470       | 2.570 | .0972  | .1012 |
| Q   | 1.024       | 1.124 | .0403  | .0443 |
| R   | 2.138       | 2.238 | .0842  | .0881 |
| S   | 1.150       | 1.250 | .0453  | .0492 |
| T   | 0.856       | 0.956 | .0337  | .0376 |
| U   | 0.270       | 0.370 | .0106  | .0146 |
| V   | 0.703       | 0.803 | .0277  | .0316 |
| W   | 0.350       | 0.450 | .0138  | .0177 |
| X   | 0.856       | 0.956 | .0337  | .0376 |
| Y   | 0.703       | 0.803 | .0277  | .0316 |
| Z   | 0.270       | 0.370 | .0106  | .0146 |

## ENVIRONMENTAL QUALIFICATIONS

|                            |                                        |                  |                       |
|----------------------------|----------------------------------------|------------------|-----------------------|
| Qualification Level        |                                        | Industrial       |                       |
| Moisture Sensitivity Level |                                        | 4mm x 5mm PQFN   | JEDEC Level 2 @ 260°C |
| ESD                        | Machine Model<br>(JESD22-A115A)        | Class B          |                       |
|                            |                                        | ≥200V to <400V   |                       |
|                            | Human Body Model<br>(JESD22-A114F)     | Class 2          |                       |
|                            |                                        | ≥2000V to <4000V |                       |
|                            | Charged Device Model<br>(JESD22-C101D) | Class III        |                       |
|                            |                                        | ≥500V to ≤1000V  |                       |
| RoHS6 Compliant            |                                        | Yes              |                       |

† Qualification standards can be found at International Rectifier web site: <http://www.irf.com>

†† Exceptions to AEC-Q101 requirements are noted in the qualification report.

Data and specifications subject to change without notice.  
Qualification Standards can be found on IR's Web site.

International  
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